Design and development of an automated temperature controller for curing ovens



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Declaration

I, Ruaan Morné Schoeman, declare that this project is my own, unaided work. It is being

submitted for the requirements for the Magister Technologiae: Engineering: Electrical to the

Department: Electronic Engineering at the Vaal University of Technology, Vanderbijlpark. It

has not been submitted before for any assessment to any educational institution.

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Dedication

This dissertation is dedicated to my wife Sharon, daughter Rushane and my parents, Gert and Evy.

Thank you for your love and support.

Abstract

Curing of materials in order to obtain different properties has been a practice for many years. New developments in composite materials increase the need to control certain variables during the curing process. One very significant variable is temperature. Temperature control by itself is an old practice, however when the need for repeatedly controlling the process accurately over long periods of time arises, a system is required that outperforms normal manual control.

One of the aspects within such a system that needs to be considered is the ability to replicate the temperatures within an oven which were originally used for a specific material's curing profile. This means that a curing profile would need to be defined, saved for later and finally be interpreted correctly by the controlling system.

Different control methods were simulated to enable the system to control the temperature which has been defined by literature. This dissertation introduces a variation on the standard control methods and shows improved results.

Switching the oven on and off in order to increase or decrease internal oven temperature seems simple, but can cause switching devices to decrease their operational life span, if not designed carefully. A combination switch was introduced which harnesses the advantages of two very common switching devices to form an improved combination switch.

Software for the personal computer environment, as well as software for the embedded environment were developed and formed a control system that produced acceptable results for temperature control. Accuracies of 98% and more were achieved and found to be acceptable according to standard engineering control practices.

An accurate temperature profile controller was designed, simulated and built in order to control the temperature inside a specific curing oven which, in turn, determined the curing properties of specific materials. The overall results were satisfactory which lead to achieving the objectives outlined in this dissertation.

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Glossary of abbreviations and definitions

A		S	
AC	Alternating current	SCR	A current controlled four-layer device
			for high power and low speed
Armature	The moving iron part of		applications electronic devices
	a solenoid or relay		
С		Snubber	An auxiliary circuit used to control
Curing	The process of setting or		the rate of rise or fall of the current
	hardening of a material		flowing into a power electronic
D			device
DIAC	A two-terminal AC device	0.01	0 : 10 : 1
5(0	that, once gated on by	SPI	Serial Peripheral Interface, a full-duplex
	sufficient forward voltage,		synchronous serial interface for
	permits the flow of current		connecting low-/medium-bandwidth external devices using four wires
	until reverse biased		external devices using four wires
		т	
DITI	Digital Infrared Thermal	Thermalset	Having the property of becoming
	Imaging		permanently hard and rigid when heated
			or cured
G			
GUI	Graphical user interface used	Thermistors	An electrical resistor whose resistance
	in the software environment		is greatly reduced by heating, used for
ı			measurement and control
I ² C	Inter-Integrated Circuit is a		
. 0	multi-master serial single-	Thermography	A technique wherein an infrared camera
	ended computer bus used to		photographically portrays an object's
	attach low-speed peripherals		surface temperature
	to a motherboard, embedded	TRIAC	A power switch that is functionally a
	systems, cell phones, or other		pair of converter-grade thyristors
	electronic devices		connected in anti-parallel
			·
М		TSVUT	Technology Station of the Vaal
Microcomputer	A microcontroller including		University of Technology
	external storage and		
	memory devices		
Р			
Pneumatics	The study of the mechanical		
aaee	properties of air and other		
	gases		
R	-		
RTD	Resistance temperature		
	detectors		

Chapter 1 Introduction and overview

1.1 Background

Thermalset is the phase change of a compound into a substantially infusible and insoluble material when it is cured by the application of heat or by chemical means (Swartz, 1984:28). Curing of materials is done at various temperatures in specially designed ovens. A material, such as silica, cures at very high temperatures between 800°C and 1200°C, depending on the materials it is mixed with. The temperature inside an oven affects the properties of the cured material. Thus the curing temperature, which is the temperature at which a cast, moulded or extruded product is subject to during curing (Swartz, 1984:7), is very important and needs to be controlled.

There are a variety of commercial devices available that could be used to monitor the temperature of a curing oven. However, for high temperature measurements, only a few devices can be utilized, depending on the accuracy and temperature ranges required (Dogan, 2002:59). Accurate measurement of temperature is not easy and to obtain accuracies better than 0.5°C requires great care.

Radio thermometry devices measure the radiation emitted by hot objects and is based upon the emissitivity of the object, which is usually not known and additionally may vary with time (Dogan, 2002:69). However, placing sensory devices inside these ovens exposes them to extreme heat environments, resulting in failure of sensors with cumulative exposure, sensory devices can also not be placed inside the curing materials as this would deform the required moulding shape.

The air temperature in an oven could be measured. However, air temperature fluctuations, variations in radiation, nonlinearities in sensor characteristics and sensor drifts need to be kept in mind (CAPGO Pty Ltd, 2010). The following sensory devices, among others, are available for measuring air temperature: thermocouples, resistance temperature detectors (RTD) and monolithic temperature sensors. These sensory devices are designed to function in harsh environmental conditions.

Switching devices are components which are used to switch loads ON and OFF. Switching either direct current (DC) or alternating current (AC) presents its own unique problems. One such problem is heat dissipation in the device itself. Thus, obtaining a suitable device that

can switch high currents required by ovens that are controlled by small signal devices (such as microcontrollers) will prove to be challenging in itself.

Sensory devices may be complemented by a microcomputer which is widely used to monitor environmental data and execute decisions based there-on. The term microcomputer is used to describe a system that includes a minimum of a microprocessor, program memory, data memory and input/output functions. Thus, a microcomputer system can be anything from a large computer having hard disks, floppy disks and printers, to a single chip computer (Dogan, 2002:5). For example, microcomputer systems could be implemented in the controlling of various processes, such as maintaining room temperature by activating or deactivating an air conditioning unit.

1.2 Problem statement

Manually controlling the operating temperatures of a curing oven at the Technology Station of the Vaal University of Technology (TSVUT) lacks accuracy and consistency. The curing process is often repeated with materials of the same type, yet the curing results with respect to the material's properties vary. This mainly occurs because the operator has to manually switch the oven's heating element ON or OFF according to personal feeling. Thus, no accurate control technique or constant evaluation parameters are applied to achieve consistency in the repetition of the thermalset or curing process.

1.3 Research methodology

- Temperature range, curing profiles, type of oven and materials to be cured will be obtained through interviews with staff at the TSVUT.
- The best switching technique for high current devices will be identified through a literature search.
- Literature on microcomputers and their communication techniques will be gathered and evaluated to determine what would be needed to control the heating modules.
- Control techniques will be investigated and applied to the embedded environment.
- Data will be collected with respect to the oven's heating characteristics.
- An algorithm will be developed based on the data obtained.
- Simulation of the algorithm in MATLAB will be done.
- A prototype controller will be designed and simulated.
- Results will be evaluated and corrections to the design will be made.

- If simulations of the control technique and communication are satisfactory, then a
 prototype printed circuit board will be developed.
- The prototype will be then tested with a curing oven.
- Improvements will be made in order to ensure consistency of repeated curing processes.

1.4 Delimitations

- The research will not include the investigation of cooling systems which could assist in the rapid cooling of materials as this will require a large budget.
- The research will not focus on industrial ovens as this research is for a specific need at the TSVUT.
- No alterations or additions can be made to the oven as specified by the TSVUT.

1.5 Importance of research

The research will benefit the TSVUT, as they will be able to produce concurrent samples of a specific curing process. Industry will also benefit from this research, as they will have an entity that could produce consistent results for use in testing phases.

1.6 Overview of the dissertation

This dissertation reports on the development of a curing oven controller which will automatically determine the characteristics of an oven and deduce control parameters to be used in the controlling action.

Chapter 2 presents the equivalent representation of an oven as an electrical circuit. It further describes different temperature sensory equipment currently available in industry. Different switching devices are presented along with various temperature control methods which are used in industrial applications

Chapter 3 introduces the parameters of the oven which are obtained from the simulation model in MATLAB. Other critical components, such as the low loss AC switch, are also presented.

Chapter 4 presents the developed control software along with measurements and tests conducted in order to prove that a curing profile can be replicated.

Chapter 5 contains the conclusions and recommendations obtained from the study.

1.7 Research outputs

This study has already produced the following peer-reviewed research outputs published by IEEE Xplore, the digital database of the Institute of Electrical and Electronic Engineers.

- A conference paper for Optim 2010, entitled "Self-tuning curing oven control" and
- A conference paper for Africon 2011, entitled "Embedded PI-bang-bang curing oven controller".

1.8 Summary

The accurate curing of materials is an important requirement of the work done by the TSVUT. It is important that the curing process of composite materials be reproduced repeatedly to ensure that the characteristics of the materials are consistent over time. Simulation, collection of data, design and development form an integral part of this research. Cooling systems will not be investigated to keep costs to a minimum in order to produce a control unit that is affordable to the TSVUT as well as to industry.

Chapter 2 Theoretical background

2.1 Introduction

The temperature profile during the curing process of composite materials determines the final characteristics of the cured sample (Bogetti & Gillespie, 1992:626). The problem however, of reproducing the same set of parameters with respect to different temperature settings for specific time periods necessitates the use of a precise controlling device.

The curing of composite materials is normally done in an industrial oven. A heating element of low resistance generates heat which is then transferred to the material or object. This can be seen in figure 1, where heat from the heating element is transferred to the object inside the oven. The heating element is normally a high power device which allows for quick heat generation. The switching of the heating element proves challenging due to the high values of current which flow through it.

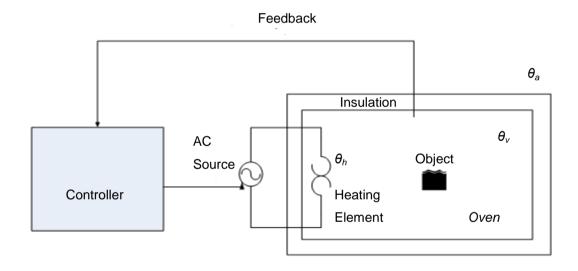


Figure 1 Representation of an electrical oven as a plant (University of EXETER, 2010)

2.2 Oven electrical equivalent model

Heat is the process of energy transfer from one body or system to another due to a difference in temperature (Kesidou & Duit, 1993:85). Thermal energy can be defined as the energy of a body which increases with its temperature. Energy transfer by heat can occur between objects through radiation, conduction and/or convection. Temperature can be used

as a measure of the internal energy. Analysis of the heat flow in an oven can either be done by means of thermodynamics or by using an electrical analogy of the heat flow path.

Heat flow can be modelled by an analogy to electrical parameters shown in table 1, where heat flow is represented by current, temperatures are represented by voltages (Schroder & De Doncker, 2000:114-117), heat sources are represented by constant current sources, thermal resistances are represented by resistors and thermal capacitances by capacitors (Birca-Galateanu, 2005).

Table 1 Equivalence between thermal and electrical entities

Thermal quantity	Unit	Electrical quantity	Unit
P - Heat flow, power	W	I – Current flow	Α
$\Delta heta$ — Temperature difference	K	V – Voltage difference	V
R _s - Thermal resistance	K/W	R – Electrical resistance	Ω
C _m – Thermal mass, capacitance	J/K	C – Electrical capacitance	F
$T_{\scriptscriptstyle th} = R_{\scriptscriptstyle th} \times C_{\scriptscriptstyle th}$ — Thermal RC constant	S	$T = R \times C$ – Electrical RC constant	S

This can be seen in figure 2, where

- R, represents the thermal resistance between the heating element and the oven,
- R₂ represents the resistance between the oven and the environment,
- C₁ represents the equivalent capacitance of the oven,
- C₂ represents the equivalent capacitance of the heating element,
- θ_a represents the ambient temperature of the environment,
- W represents the power dissipated in the heating element,
- θ_{v} represents the oven temperature and
- θ_h represents the heating element temperature.

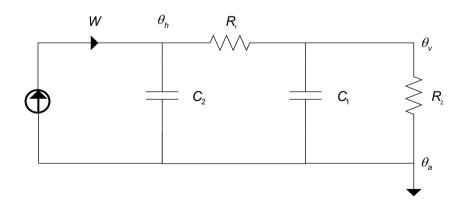


Figure 2 Electrical equivalent of a thermal oven (University of EXETER, 2010)

Capacitor C_2 can be neglected from the equivalent diagram as the capacity of the element to store heat is small in comparison to that of the oven capacity to store heat. Subsequently figure 3 shows a simplified diagram that can be used as the electrical equivalent of a thermal oven with input voltage $v_i(t)$, input current i(t) and output voltage $v_o(t)$.

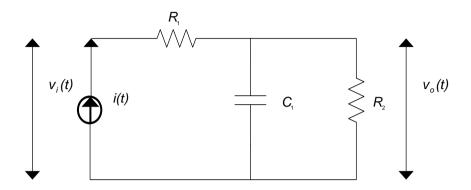


Figure 3 Simplified electrical equivalent of a thermal oven

Finding the transfer function of this circuit is now simplified, which may be done by applying basic electrical principles (see table 2) of current and voltage rules as well as the relationships between voltage, current and impedance (Nise, 2000:52).

Table 2 Voltage and current and current and voltage relationships, summarized (Nise, 2000:52)

Component	Voltage to Current	Current to Voltage	Impedance
Capacitor $V_{c}(t) = \frac{1}{C} \int_{0}^{t} i_{c}(t) dt$		$i_{c}(t) = C \frac{d}{dt} v_{c}(t)$	$Z_{c}(s) = \frac{1}{Cs}$
Resistor	$V_{r}(t) = Ri_{r}(t)$	$i_{r}(t) = \frac{v_{r}(t)}{R}$	$Z_{r}(s) = R$
Inductor	$V_{i}(t) = L \frac{d}{dt} i_{i}(t)$	$i_{j}(t) = \frac{1}{L} \int_{0}^{t} v_{j}(t) dt$	$Z_{i}(s) = Ls$

The time domain equation can be found by applying Kirchhoff's voltage law:

$$v_i(t) = R_i i(t) + v_o(t) \qquad \dots (1)$$

Where $v_i(t) \equiv \text{input voltage in V}$

i(t) = input current in A

 $R_{_{I}}$ = thermal resistance between heating element and oven in Ω

 $v_{o}(t) \equiv \text{output voltage in V}$

Using table 2 the current flowing through the capacitor can be written as:

$$i(t) = C_1 \frac{d}{dt} V_o(t) \qquad \dots (2)$$

Where i(t) = charge or discharge time in s

 $v_{o}(t)$ = resistance in series in Ω

 $C_1 \equiv \text{capacitance of the circuit in F}$

By substituting (2) into (1) results in:

$$V_i(t) = R_i C_i \frac{d}{dt} V_o(t) + V_o(t) \qquad ... (3)$$

In Laplace format

$$v_i(s) = [R_iC_is + 1]v_os$$
 ... (4)

The overall transfer function is therefore defined as:

$$\frac{v_o(s)}{v_i(s)} = \frac{1}{R_1 C_1 s + 1}$$
 ... (5)

The time constant is often related directly to the circuit RC value (the product of the resistance in Ohms and the capacitance in Farads) or to its L/R value (the ratio of the inductance in Henrys to its resistance in Ohms)(IEEE EED, 2000:710), which is expressed mathematically as:

$$T = RC$$
 ... (6)

Where T = charge or discharge time in s

 $R = \text{resistance in series in } \Omega$

C = capacitance of the circuit in F

Thus, by substituting equation (6) into equation (5) yields following transfer function:

$$\frac{v_o(s)}{v_i(s)} = \frac{1}{Ts+1} \qquad \dots (7)$$

$$= \frac{T^{-1}}{s + T^{-1}} \qquad ... (8)$$

In order to obtain a transfer function with reference to time requires the application of the inverse Laplace transformations (Nise, 2000:40), as can be seen in table 3

Table 3 Laplace transformations (Boyd, 2009)

Function	Laplace	Function	Laplace	Function	Laplace
1	1 s	cos at	$\frac{s}{(s^2+a^2)}$	sin at	$\frac{a}{(s^2+a^2)}$
e ^{at}	1 s - a	e ^{at} cos bt	$\frac{(s-a)}{[(s-a)^2+b^2]}$	e ^{at} sin bt	$\frac{b}{[(s-a)^2+b^2]}$
t ⁿ	$\frac{n!}{s(n+1)}$	uc(t)	$\frac{e^{-CS}}{s}$	uct(t)f(t-c)	$e^{-CS}F(s)$
$t^{p}, p > -1$	$\frac{G(p+1)}{s(p+1)}$	t ⁿ e ^{at}	$\frac{n!}{(s-a)(n+1)}$	e ^{Ct} f(t)	F(c – s)

Applying the inverse Laplace transform for a unit step function with a magnitude of one, results in the following:

$$v_i(s) = \frac{1}{s} \qquad \dots (9)$$

$$v_o(s) = v_i(s) \frac{T^{-1}}{s + T^{-1}}$$

$$v_o(s) = s \frac{T^{-1}}{s(s+T^{-1})}$$
 ... (10)

$$v_o(t) = 1 - e^{-\frac{t}{T}}$$
 ... (11)

Substituting equation (6) into equation (11) yields an equation which represents the output according to electrical terminology:

$$V_o(t) = 1 - e^{-\frac{t}{R_i C_i}}$$
 ... (12)

2.3 Thermal measuring devices

Heat measurements can be made by making use of various different sensory devices. These could include thermistors, RTD's, thermocouples and thermography sensors. However, when temperatures exceed 800°C, few sensory devices have the ability to measure and interpret temperatures correctly.

2.3.1 Thermocouples

Only two devices can be used in the measurement of very high temperatures, namely thermocouples and thermography sensors (OMEGA Engineering, 2005).

A thermocouple (TC) consists of two wires of different conductive material, connected to each other by means of two junctions forming an electrical circuit. If one junction is at temperature θ_{Ref} and the other at θ_{Tip} , then an electromotive force (EMF) is generated in the circuit, which is dependant on the materials and temperatures θ_{Ref} and θ_{Tip} , known as the Seebeck effect (Tong, 2001).

Thomas Johann Seebeck discovered the existence of thermoelectric currents while observing electromagnetic effects associated with bismuth-copper and bismuth-antimony circuits (ASTM Committee E-20 on Temperature Measurement, 1974). The Seebeck effect entails the overall conversion of thermal energy into electrical energy where the Seebeck voltage can be represented as:

$$E = a(\theta_{Tip} - \theta_{Ref}) \qquad \dots (13)$$

Where $E \equiv \text{electromagnetic force in mV}$

a ≡ proportionality constant known as the Seebeck coefficient

 θ_{Ref} = hot junction temperature in °C

 $\theta_{Tip} \equiv \text{cold junction temperature in } ^{\circ}\text{C}$

Assume that the Seebeck coefficients of two different metallic materials and their lead wires are S_A , S_B , and S_{Lead} respectively. All three Seebeck coefficients are functions of temperature. The output voltage (v_{out}) measured at the gauge seen in figure 4 can be represented as:

$$\begin{split} v_{out} &= \int_{\mathsf{Gage}}^{\mathsf{Ref}} S_{\mathsf{Lead}}(\theta) \frac{d\theta}{dx} dx + \int_{\mathsf{Ref}}^{\mathsf{Tip}} S_{\mathsf{A}}(\theta) \frac{d\theta}{dx} dx + \int_{\mathsf{Ref}}^{\mathsf{Gage}} S_{\mathsf{Lead}}(\theta) \frac{d\theta}{dx} dx + \int_{\mathsf{Tip}}^{\mathsf{Ref}} S_{\mathsf{B}}(\theta) \frac{d\theta}{dx} dx \\ &= \int_{\theta_{\mathsf{Ref}}}^{\theta_{\mathsf{Tip}}} S_{\mathsf{A}}(\theta) d\theta + \int_{\theta_{\mathsf{Tip}}}^{\theta_{\mathsf{Ref}}} S_{\mathsf{B}}(\theta) d\theta \\ &= \int_{\theta_{\mathsf{Def}}}^{\theta_{\mathsf{Tip}}} \left[S_{\mathsf{A}}(\theta) - S_{\mathsf{B}}(\theta) \right] d\theta & \dots (14) \end{split}$$

Where θ_{Ref} = temperature at the reference point in °C

 θ_{Tip} = temperature at the probe tip in °C

 S_{Lead} = Seebeck coefficients for connecting lead

 $S_A \equiv \text{Seebeck coefficient, material A}$

 S_B = Seebeck coefficient, material B

 v_{out} = electromagnetic force produced by system in mV

According to equation (14) the voltage induced by the temperature and/or material mismatch of the lead wires will cancel, whereas in reality the lead wires will introduce noise into the system. If the Seebeck coefficient functions of the two thermocouple wire materials are precalibrated and the reference temperature θ_{Ref} is known, then the temperature at the probe tip becomes the only unknown and can be directly related to the output voltage.

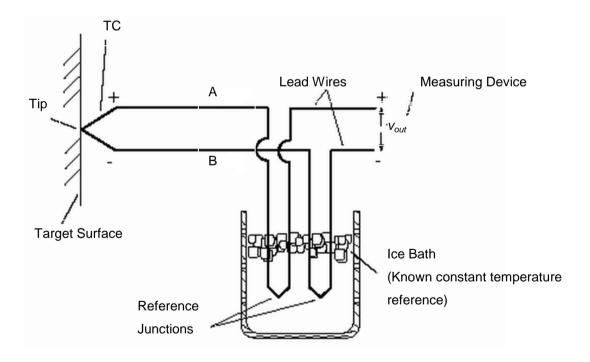


Figure 4 Thermocouple setup (Duff and Towey, 2010)

If the Seebeck coefficients are constant across the targeted temperature range, then the integral in equation (14) can be simplified as seen in equation (15), allowing for the temperature at the probe tip to be calculated as:

$$V_{out} = (\theta_{A} - \theta_{B})(\theta_{Tip} - \theta_{Ref})$$

$$\therefore \theta_{Tip} = \theta_{Ref} + \frac{V_{out}}{\theta_{A} - \theta_{B}}$$
... (15)

In practice, manufacturers will provide calibration functions for their products. These functions are usually high order polynomials and are calibrated with respect to a certain reference temperature, normally 0°C or 32°F. Assume that the coefficients of the calibration polynomials are θ_0 , θ_1 , θ_2 , up to θ_n , then the temperature at the probe tip can then be related to the output voltage as shown in equation (16) (Potter, 1997).

$$\theta_{Tip} = \theta_0 + \theta_1 V_{out} + \theta_2 V_{out}^2 + \cdots + \theta_n V_{out}^n \qquad \dots (16)$$

A thermocouple is not an absolute temperature sensor (Bentley, 1984). In other words, a thermocouple requires a reference of known temperature which may be provided by ice water as illustrated by figure 4. While ice water is easy to obtain and has a well known reference, it's not a practical solution out side the laboratory. Thus, common commercialized thermocouples often include another temperature sensor, such as a thermistor, to provide a reference of the ambient temperature.

Table 4 Thermocouple comparison (Efunda, 2010)

	Temperature	Temperature			BS Colour	ANSI
Туре	range °C	range °C	Tolerance class one	Tolerance class two	code	Colour code
	(continuous)	(short term)	(°C)	(°C)		
К	0°C to +1100°C	+1300°C		±2.5°C between −40 °C and 333°C ±0.0075°C ×T between 333°C and 1200°C	-	-
J	0°C to +700°C	+800°C	and 375°C ±0.004°C ×T between	±2.5°C between −40°C and 333°C ±0.0075°C ×T between 333°C and 750°C	()+	-
R	0°C to +1600°C	−50°C to	±[1°C + 0.003°C ×(T - 1100°C)] between	±1.5°C between 0°C and 600°C ±0.0025°C ×T between 600°C and 1600°C	-	Not defined.

According to EN/ANSI standards and most common industrial applications, the thermocouple is often used for temperature measurements between - 40°C and 1800°C (European Solar Thermal Industry Federation., 2007:11). Thermocouples can be classified with respect to their material and their operational temperature (see table 4).

2.3.2 Thermography

Every object radiates heat and emits a certain wavelength which corresponds to the energy it is radiating. Thus thermography can be defined as images produced by infrared cameras showing temperature differences in objects by making use of the infrared spectrum (Dictionary.com, 2010). Thermography had its early origin in 480 BC when Hippocrates experimented with mud which he applied to a human body in order to determine which parts of the body would dry the mud first (Proactive Wellness & Imaging Center, 2011). During the early 1950's, infrared spectrometry was used to monitor the movement of soldiers during night time exercises. Since then, the technology has been made available for commercial use and research within this field has increased rapidly.

Thermography has then been applied to the electrical environment (see figure 5). Fuses emit different heat levels that are represented by different colours. Calibrating these colours (spectrum occupancies) with radiating heat levels enables one to determine the temperature values for different parts of the fuse. The approximate temperature range of thermography is from -20°C to over 2,000°C. This makes it suitable for measuring high temperature values during a curing process.

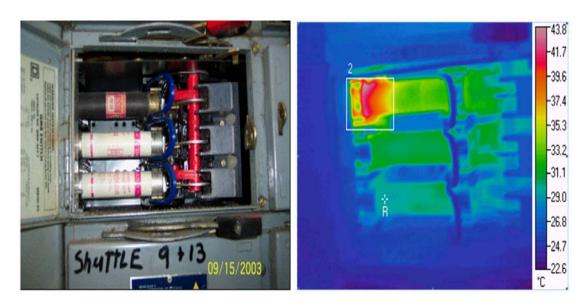


Figure 5 Thermogram of electrical fuses (POWER PLUS ENGINEERING INC, 2003)

2.4 Electrical switching devices

One of the simplest devices found in electrical circuits would be the switch. This device is used to close (complete) or break an electrical circuit, which in turn will allow current either to flow through or not to flow. Switching devices are abundant and come in a variety of different shapes and sizes, yet can be grouped into either mechanical or solid-state devices.

2.4.1 The relay

A device which allows an electrical circuit to control the ON and OFF state without human intervention is a relay (grouped as a mechanical switching device). As can be seen in figure 6, an inductor is used to generate a magnetic field which in turn attracts a contact, thereby closing the circuit and allowing current to flow. This inductor can be energised by other circuits which becomes the controller circuit. Contact bounce is always present during the switching period (Johler, 2000:83-93).

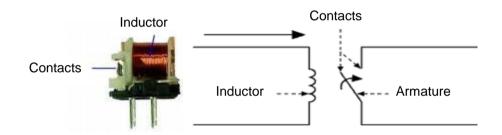


Figure 6 Representation of a relay and its symbol

Contact bounce elates to when contacts strike each other, their momentum and elasticity acts together to cause bounce. This often forms arcing between the contacts, which will in turn lead to contact burn, the process where carbon is deposited onto the contact surfaces of the relay. Repeated carbon deposits increase the resistance between the contacts, thereby limiting the flow of current flow and reducing the performance of the switching device. Several techniques have been developed to reduce carbon deposits during contact bounce.

Some manufacturers allow the contacts to be submerged in oil, thereby reducing the oxygen needed for burning (Buschart & Kuczka, 1992:293-299). Contact bounce also leads to high transients, which could be detrimental to surrounding circuits. Figure 7 illustrates contact bounce which exits during the switch activation and deactivation periods respectively.

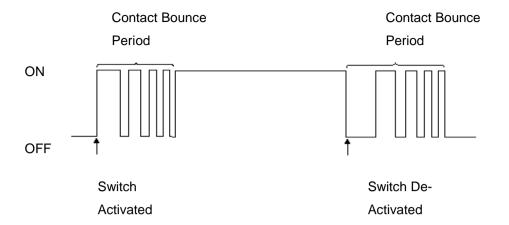


Figure 7 Relay contact bounce during activation and deactivation process (Electronix Express, 2010)

2.4.2 Silicon controlled rectifiers

A silicon controlled rectifier (SCR) can be defined as a four-layer device controlled by current for high power and low speed applications (IEEE EED, 2000:646). SCRs can only be ON or OFF, with no intermediate operating states like transistors. Once latched on, the gate current can be removed and the device will remain on until the anode current becomes negative, or the current through the SCR falls below its holding current. A disadvantage is that a commutation circuit is often needed for forced turn-off (IEEE EED, 2000:646). Figure 8 illustrates the layer composition and ON/OFF states of this device.

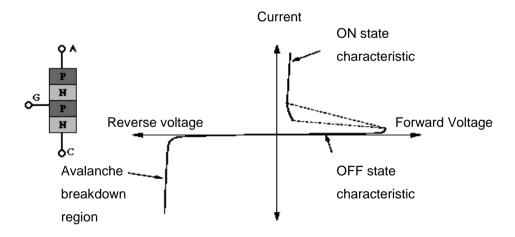


Figure 8 A SCR's characteristic voltage/current curve (American Microsemiconductor Inc., 2010)

A thyristor or SCR is seen as a switch (Taib et al., 1992:568-580). The advantage of this device is that it can operate without involving arcing, thereby negating mechanical wear. The drawback of this device is the internal resistance R_f present between the positive and

negative (PN) junctions which will generate heat when current is allowed to flow. Figure 9 illustrates the equivalent circuit for the PN junctions, while figure 10 illustrates the forward resistance, which will generate heat due to current flow.

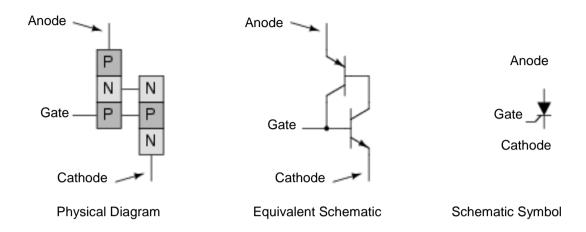


Figure 9 SCR PN layer equivalent circuit

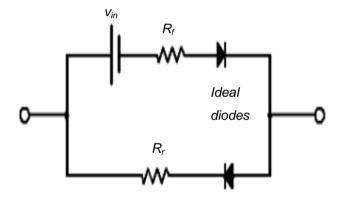


Figure 10 SCR diode equivalent circuit

2.4.3 Triode for alternating currents

A triode for alternating currents (TRIAC) is a component which is equivalent to two SCRs joined in anti-parallel (paralleled but with the polarity reversed) configuration, having their gates connected together. The formal name for a TRIAC is a bidirectional triode thyristor (Gentry et al., 1965). This results in a bidirectional electronic switch that can conduct current in either direction when it is triggered, and thus does not have any polarity. Figure 11 shows the voltage/current curve of the TRIAC and the areas where the device conducts.

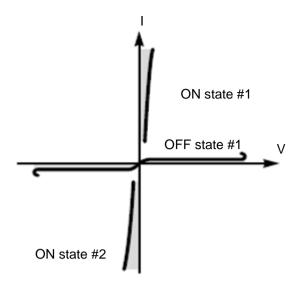


Figure 11 A TRIAC characteristic voltage/current curve (American Microsemiconductor Inc., 2010)

The device can be triggered by either a positive or a negative voltage being applied to its gate electrode. Once triggered, the device continues to conduct until the current through the device drops below a certain threshold value (the holding current), such as at the end of a half-cycle of an alternating current. This makes the TRIAC a very convenient switch for AC circuits, allowing the control of very large currents with milliampere-scale control currents.

TRIACs are able to achieve fast switching speeds with no contact bounce as they area solidstate devices. However, one drawback exists which is the internal resistance, which is present between the PN junctions in the activated state (reverse and forward). Following Ohms law, the internal resistances R_f and R_r will produce heat, which will need to be dissipated when current is flowing. Additional heat dissipation devices, such as heat sinks or cooling fans, are therefore required to keep the device operating correctly.

2.4.4 Snubber circuits

A snubbing circuit can be defined as an auxiliary circuit used to control the current rise and fall rate, flowing into a device or the voltage fall or rise rate across the device during turn-off (IEEE EED, 2000:658). Using a snubber circuit assists in turning-off a device as well as to prevent premature triggering, which may be caused by voltage spikes originating from the mains supply.

The function of the snubber circuit is to protect semiconductor devices by

- limiting device voltages during turn-off transients,
- limiting device currents during turn-on transients,

- limiting the rate-of-rise (di/dt) of currents through the semiconductor device at device turn-on,
- limiting the rate-of-rise (dv/dt) of voltages across the semiconductor device at device turn-off and
- shaping the switching trajectory.

Figure 12 is an example of such a circuit which could be used to protect a SCR against switching transients.

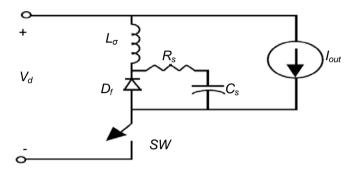


Figure 12 A snubber circuit

A gate resistor or capacitor may be connected between the gate and anode to further prevent false triggering. That, however, increases the required trigger current and / or adds latency (capacitor charging). A DIAC is often used to drive the gates of both TRIACs and SCRs as can be seen in figure 13.

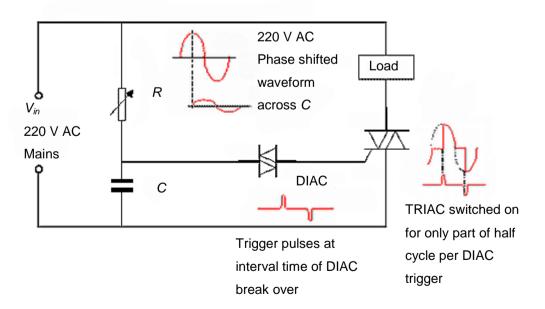


Figure 13 A DIAC used to drive a TRIAC circuit (Coates, 2008)

The DIAC is designed to have a particular break over voltage, which can be in the region of approximately 29 V, when a smaller voltage is applied of either polarity, the device remains in a high resistance state with only a small leakage current flowing. When the break over voltage is achieved of either polarity, the device exhibits a negative resistance which results in its characteristic curve as shown in figure 14.

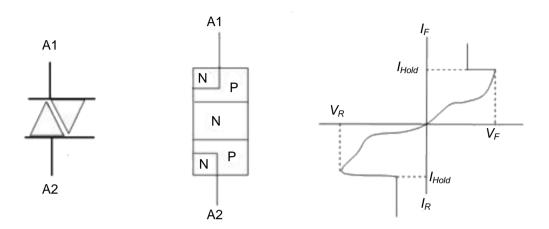


Figure 14 DIAC characteristic curve (Uddin, 2011)

When the voltage across the DIAC exceeds the break-over voltage, an increase in current is observed accompanied by a drop in the voltage across the DIAC. Applying Ohm's law an increase in current through a component should cause an increase in voltage across that component. However, the opposite effect is happening here, exhibiting negative resistance at break-over.

2.5 Control theory

Standard control theory suggests that there are two classic types of control methodologies namely feedforward and feedback control (Cervin et al., 2002:25). The input to a feedback controller is the same as what it is trying to control (the controlled variable is fed back into the controller). A sensory device measures the controlled variable, feeds it back to the controller which in turn adjusts the output. However, feedback control normally results in periods where the controlled variable is not at the desired set-point. This is where feedforward control can be an asset to the control process, as it could avoid the slowness of feedback control. Figure 15 illustrates how the feedback controller can be simplified. Evaluating feedforward control, disturbances are measured and potentially accounted for before they affect the system. A disadvantage of feedforward control lies in the fact that the effect of the disturbances needs to be predicted as accurately as possible, and all disturbances must be measured.

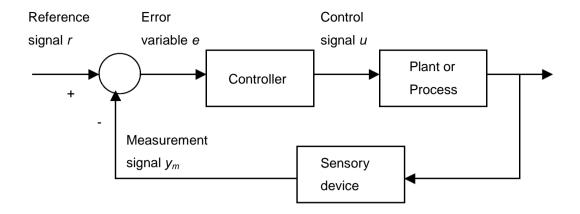


Figure 15 A feedback control system

Achieving the advantages of both these methodologies, combinations of feedback and feedforward control is applied to control processes. Some examples include dead-time compensation and inverse response compensation. Dead-time compensation is used to control devices that take a long time to show any change to a change in input, for example the temperature rise inside an oven when it has been switched on.

Dead-time compensation control uses an element to predict how changes made by the controller will affect the controlled variable in the future. The controlled variable is also measured and used in feedback control. Inverse response compensation involves controlling systems where a change at first affects the measured variable one way, but later affects it in the opposite way.

A variety of applications use feedback control. The benefits of this control method are the possibility of keeping a parameter's value at a fixed level or changing it quickly, despite disturbances that might occur. The basic goal of any controller is to achieve stability in controlling the process (Beardmore, 2006). This means that a controlled system should remain stable within its assigned parameters. The quality of the control can be measured by analysing the accuracy, speed and robustness of a control system.

In feedback control it is desirable to have the output signal follow the reference signal as precisely as possible. If the output signal of the process increases, the measurement signal needs to follow it. This results in the error signal and control signal becoming smaller. This forces the process output signal to decrease, which means that the error signal tends towards zero and the output of the process towards the reference value. Analysing the stability of a control system can be done with frequency response of an open-loop system.

Frequency response of an open-loop system indicates how the system behaves without the feedback loop. The structure of an open-loop system is presented in figure 16.

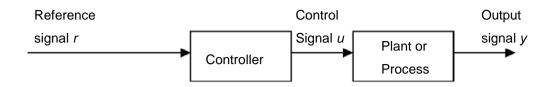


Figure 16 An open-loop control system

Frequency response is a function of ω (frequency) (Tham, 1999). The frequency function gives the gain (amplitude) and phase of a sinusoid signal, which is fed into the system, at every frequency of the output. The frequency response can be calculated from the transfer function of the system by replacing s with $j\omega$ shown in figure 17.

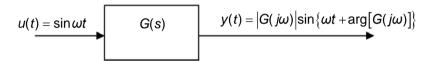


Figure 17 Sinusoidal input and transfer function

Drawbacks of open-loop control are that it requires perfect knowledge of the system and it assumes that there are no disturbances in the system.

2.5.1 Types of controllers

Many previous control valve systems were implemented using mechanical systems or solid state electronics. Pneumatics was often used to transmit information and apply control using pressure. However, most modern industrial control systems now rely on computers as the controller. Obviously it is much easier to implement complex control algorithms on a computer than using a mechanical system.

For feedback controllers there exists a few examples. The most common is a thermostat that just turns the power on if the temperature falls below a certain value and turns the power off if it exceeds a certain value. This is called bang-bang (BB) control (Dogan, 2002). Another simple type of controller is a proportional (P) controller, where, the controller output (control action) is proportional to the error in the measured variable. The error is defined as the difference between the current value (measured) and the desired value (set-point). If the

error is large, then the control action is large. This can be represented mathematically by equation 17:

$$c(t) = K_c e(t) + c_s \qquad \dots (17)$$

Where e(t) = error value fed back

 $K_c \equiv \text{controller's gain value}$

 c_s = steady state control value

It is necessary to maintain the variable at the steady state when there is no error. The gain (K_c) will be positive if an increase in the input variable requires a decrease in the output variable (direct-acting control), and it will be negative if an increase in the input variable requires an increase in the output variable (reverse-acting control). A typical example of a reverse-acting system is controlling the flow of cooling water, if the temperature increases, the flow must be increased to maintain the desired temperature.

Although P-control is simple to understand, it has drawbacks. The biggest problem is that for most systems it will never entirely reduce the error. This is because when the error is zero, the controller only provides the steady state control action so the system will settle back to the original steady state. Having large gains can lead to system instability or can require physical impossibilities, such as infinitely large valves. In systems with high controller gains, instability is mediated primarily through overcompensation (Loannou & Kokotovic, 1984). Subsequently P-control is not capable of making the output equal to the reference and there will be steady-state deviation.

Another example of a controller is a proportional-integral (PI) controller which adds another term to the controller equation (see equation (18)).

$$u(t) = K_c \left(e(t) + \frac{1}{T} \int_0^t e(t)dt \right) \qquad \dots (18)$$

Where $T \equiv \text{integration time constant}$

 $K_c \equiv \text{controller's gain value}$

e(t) = error value

If the controller is tuned to be slow and T is large, then the controller first acts such as a P-controller. However as the integration starts to take affect, the steady-state deviation goes

slowly to zero. PI-control is therefore a control process where the value of the output signal is based on the error between the target value and the actual (measured) value of the controlled variable, as well as how long that error has existed.

The proportional-integral-derivative (PID) control can be defined as a control scheme whereby the signal that drives the actuator equals the weighted sum of the difference between the time integral of the difference, and time derivative of the difference between the input and the measured actual output (IEEE EED, 2000). Figure 18 shows a commercially available embedded PID-controller.



Figure 18 Industrial PID controller (Nippon Instruments (India) pvt, 2011)

The equation of a PID-controller (equation (19)) has three terms, P, I and D-terms. The derivative term acts as a predictor, because the speed of change of the error signal affects the control signal. The derivative term has a large effect in systems where disturbances are present, because disturbances often occur quickly. This means that fast changes in an error signal might push the process into an unstable state. On the other hand, the derivative term might speed up the controlled system.

$$u(t) = K_p e(t) + K_i \int e(t)dt + K_d \frac{d}{dt} e(t) \qquad ... (19)$$

Where $K_p \equiv \text{proportional gain}$

 $K_i \equiv \text{integral gain}$

 $K_d \equiv \text{derivative gain}$

e(t) = error

The requirements set for a controller can be contradictory. A controlled close-loop system should be stable and the performance of the controller should be efficient, meaning that the control must be quick and reliable. For example, the better the performance of the controller, the less stable the close-loop system. That is why a compromise has to be made to fulfil all the requirements. The goal is to make the system fast, but not to push it close to the oscillation boundary, where small sudden changes in the system could make the system unstable.

The choosing of the controller's parameters is process sensitive. One need to use different parameters in fast and slow processes. The disturbances also affect the choice of parameters. Techniques used for choosing the parameters used in P, PI, or PID-control, include the step response method or oscillation boundary method, which is based on frequency analysis. The step response method can be used to tune the parameters of a controller, if it is possible to feed a step into an open-loop system (no control or feedback).

If a step of height K_1 (in °C) is fed into the system and the output of the system behaves as in figure 19, then a tangent line can be drawn at the infliction point of the output signal. The height of the output signal is then K_2 (in °C), the delay time is T_1 (in seconds) and the rising time is T_2 (in seconds), which can be calculated using figure 19.

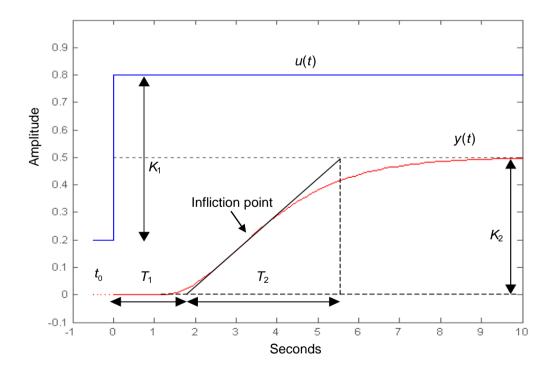


Figure 19 Step response of a system

Once values for K_1 , K_2 , T_1 , and T_2 have been obtained, then the gain, integration time and derivative could be calculated for each controller by either the Ziegler-Nichols or Cohen equation tables. The Ziegler-Nichols method of calculating the parameters for P, PI or PID-controllers is shown in table 5.

Table 5 Controller parameters for a step response method using Ziegler-Nichols (Dogan, 2002)

Controller	Gain <i>K</i>	Integration Time T ₁	Derivation Time T_D
Р	$P \qquad \qquad \frac{K_1 T_2}{K_2 T_1}$		Not applicable
PI	$0.9\frac{K_1T_2}{K_2T_1}$	3.37,	Not applicable
PID	$1.2\frac{K_1T_2}{K_2T_1}$	2 <i>T</i> ,	0.5 <i>T</i> ,

2.6 Summary

In this chapter, an equivalent electrical circuit representing the properties of a thermal oven have been presented. Different types of thermal measuring techniques and devices have been discussed and control methods used in industry have been presented.

The next chapter will present characteristic data of the oven, a MATLAB model and algorithm. The progression from an analogue- to digital solution will be discussed and the power switch combination will be shown.

Chapter 3 Simulation and experimental validation

3.1 Introduction

This chapter will introduce data of a curing oven. An analysis of this data will be shown in order to verify the mathematical model in Chapter 2. It will further present the microcontroller logic and design of the combination switch.

3.2 Temperature measuring setup

In order to work towards the model presented in equation (12), measurements with respect to temperatures in and around the oven had to be obtained. Figure 20 presents the temperature measuring setup where five type K-thermocouples were used to obtained temperatures, which were interpreted by a PICOSCOPE data logger (TC-08).

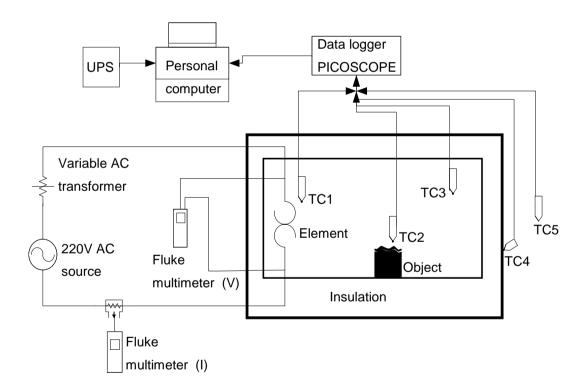


Figure 20 Temperature measuring setup

The PICOSCOPE incorporates Seebeck coefficients for type J and K thermocouples and different coefficients can be used with specific thermocouples on specific channels. Each channel had been setup to interpret type K-thermocouples. All data collected was

transferred in real time to a personal computer for analysis and normalization. Thermocouples one to five represent:

- TC1 the ambient temperature,
- TC2 the insulation temperature,
- TC3 the heating element temperature,
- TC4 the oven air temperature and
- TC5 the object temperature.

A multimeter (FLUKE FI223) was used to obtain readings of the AC voltage source applied to the element. Another multimeter (FLUKE FI223 with AC current probe FLUKE FC212) was used to obtain readings of AC current drawn by the heating element. A variable AC transformer was used to limit the amount of energy applied to the heating element in order to keep the measurements within range of the test equipment as shown in figure 20.

3.3 Initial oven characteristic data

Using the equipment shown in figure 20, various data points were obtained and processed in graphical form using MATLAB 7.6.0 (see figure 21). The set-point temperature for the experiment was set to 684°C as this was within limits of the thermocouples and other test equipment. In order to analyse the data and obtain an algorithm for the curves, normalization had to be applied (see figure 22). This normalization will also be relevant to later mathematical models used to simulate the controller. Contrasting figure 21 and figure 22, and specifically the object temperature reveals that the heating element does store heat energy, which will be an important factor when designing the controller.

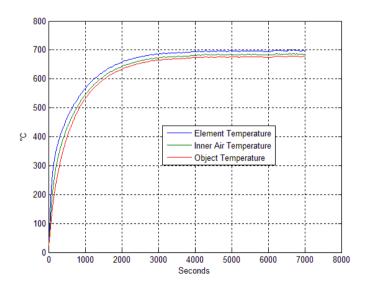


Figure 21 Data obtained for the oven in the ON position

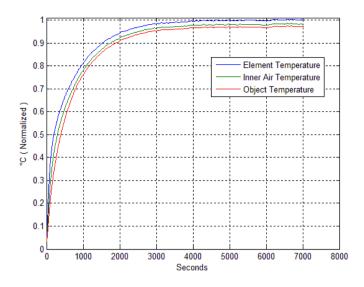


Figure 22 Normalized data obtained for the oven in the ON position

To verify that the shape of the object temperature was not accidental, different shaped objects were placed inside the oven with the experiment repeated. Figure 23 shows different object temperatures measured over a period of 4500 seconds. This proves that the temperature curves follow the same basic shape and that applying curve analysis to this type of graph would be acceptable.

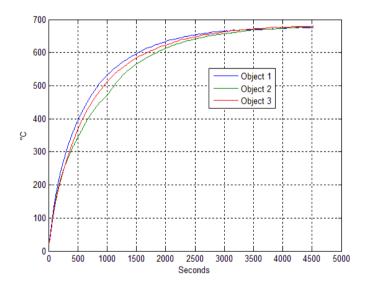


Figure 23 Different objects' temperature curves

Figure 24 shows different object temperatures with corresponding measurements of the oven's air temperature.

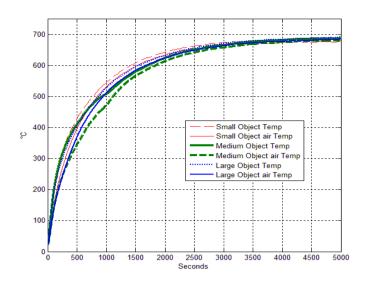


Figure 24 Object temperatures and corresponding oven inner air temperature curves

The readings are those obtained from TC2 and TC3 shown in figure 20. This figure was also used to determine if a relationship exists between air and object temperatures.

Curve analysis is the process, by which the equivalent mathematical model is compared to the data of the experimental model. MATLAB was used to obtain a curve fitted mathematical model (see figure 25).

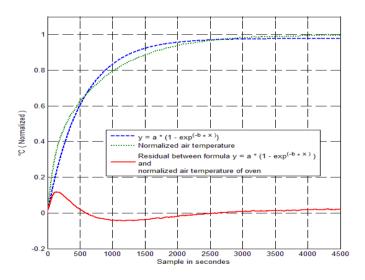


Figure 25 MATLAB curve for data collected, mathematical model fitting and residuals

CURVE EXPERT a software package was used to verify results presented from MATLAB. The fitting software uses either standard mathematical models or models developed by the user. Figure 26 and figure 27 show the analysis done by CURVE EXPERT.

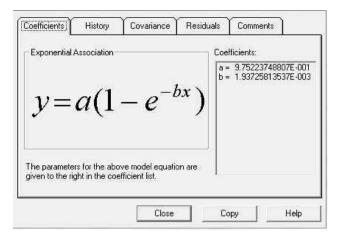


Figure 26 CURVE EXPERT data, mathematical model fitting and residuals

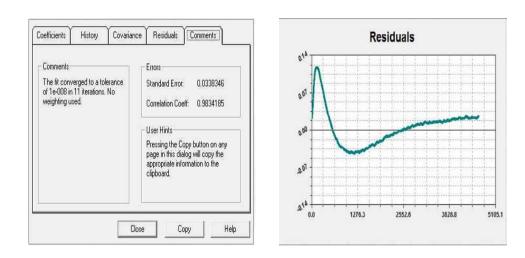


Figure 27 CURVE EXPERT mathematical model coefficients and standard error

The blue line in figure 25 represents the mathematical model fitted to the data curve shown in green. The following mathematical model equation fits the data set with some residual.

$$y = a\left(1 - e^{\left(-bx\right)}\right) \tag{20}$$

Where $y = \text{temperature in } ^{\circ}\text{C}$

 $a \equiv \text{constant as } 9.75223$

 $b \equiv \text{constant as } 1.93725$

x = time in seconds

The residuals from figure 25 and figure 27 are similar and therefore prove that the model used in figure 3 in Chapter 2 to represent the oven in its electrical form is correct. The derived equation (12) and the experimental acquired equation (20) are similar confirming the approach used is correct.

3.4 MATLAB model

The simplified basic model from Chapter 2 has been redrawn in MATLAB. This was done in order to test the fitted curve found as applied to the model for simulation purposes. The model shown in figure 28 was then later developed to include a control system, which could be simulated in MATLAB before applying it to the microcontroller for regulating the temperature of the oven.

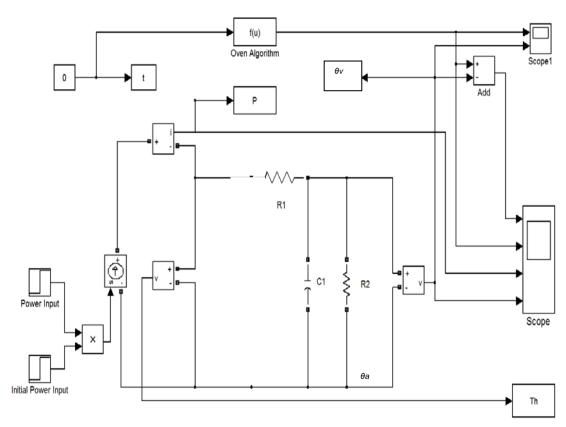


Figure 28 MATLAB representation of the simplified electrical oven model

3.4.1 Control of air temperature using Bang-Bang, Pl and PID control

Using the Ziegler-Nichols criterion, the parameters of the controller can be calculated from the measurements taken. The parameters of the controller are presented in table 5.

MATLAB was used to implement a control method to the model as shown in figure 29. Using the Ziegler-Nichols step response technique, control parameters of the oven plant were determined and simulated in MATLAB for the PI control method. The PI control method was chosen because of its smaller over-shoot when nearing the set-point. The simulation setup used in MATLAB is shown in figure 29.

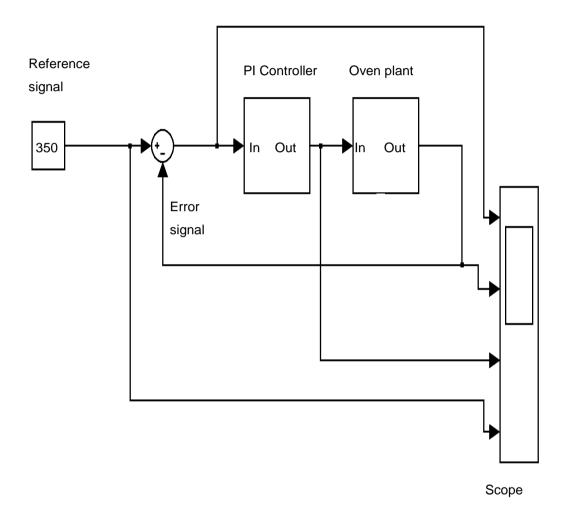


Figure 29 MATLAB model of the simplified oven model and controller

3.4.2 Stability analysis of the analogue solution

Using MATLAB's SISO tools, a stability analysis was done using a step response method (see figure 30). As a result of a step input, the Open-Loop Bode and Root Locus results (see figure 31), a conclusion can be drawn that the control parameters for K_p and K_i (determined using table 5), for this specific model are within range and that the control loop is stable.

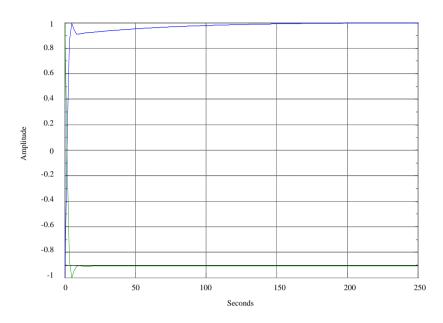


Figure 30 Step response analysis graph

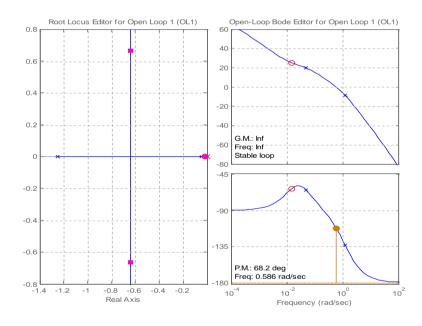


Figure 31 MATLAB SISO tools stability analysis graph

3.5 Progression from analogue to digital solution

According to Schoeman (2011), it is suggested that each control technique (BB, PI and PID) has its own individual advantages and disadvantages. The BB technique has a very fast rise time, but once the set-point is reached the variant between the switch on and switch off

temperatures is high. The PI control technique has a very stable and small variant when the set-point is reached, but its rise time towards the set-point is slow.

PID is an improvement on PI in respect that the rise time toward the set-point is much faster, but not as fast as BB (Schoeman, 2011). It also has a characteristic of over-shoot when the set-point is reached and the settling time is therefore increased when compared to PI control. This can be seen in figure 32, which was obtained using simulation models in PROTEUS VIRTUAL SYSTEM MODELLING (PVSM) 7.2. Different control methods were applied via embedded software programs using a microcontroller circuit (see figure 33).

PVSM 7.2 combines mixed mode SPICE circuit simulation, animated components and microprocessor models to facilitate co-simulation of complete microcontroller based designs (Labcenter Elctronics, 2010). It is possible to develop and test such designs before a physical prototype is constructed. At the heart of PVSM is ProSPICE. This is an established product that combines a SPICE3f5 analogue simulator kernel with a fast event-driven digital simulator to provide seamless mixed-mode simulation (Labcenter Elctronics, 2010). The use of a SPICE3f5 kernel allows for the use of the numerous manufacturer-supplied SPICE models, around 6000 of these are included with the package. PVSM 7.2 includes a number of virtual instruments including an oscilloscope, logic analyser, function generator, pattern generator, counter timer and virtual terminal as well as simple voltmeters and ammeters. In addition, dedicated Master/Slave/Monitor mode protocol analysers are provided for SPI and I²C communications.

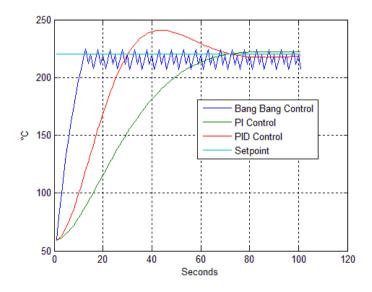


Figure 32 Control methods' step response graphs (Schoeman, 2011)

The parameters used (K_1 , K_2 , T_1 , T_2) in the microcontroller software were determined using Ziegler-Nichols' method shown in table 5. In order to overcome the disadvantages of PI and BB control, it was decided to apply a combination control where the controller would initially use BB control to achieve a faster rise time towards the set-point and then switch over to PI control at 90% of the setpoint value.

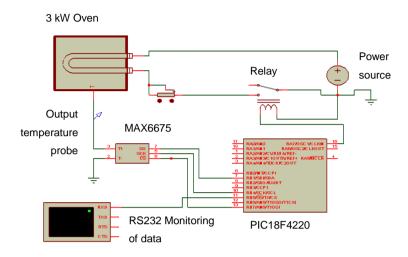


Figure 33 Proteus circuit used for simulation of control methods

Initial simulations showed very little improvement. However, once the PI parameters where updated during the BB control phase, the application of using two control methods showed a faster rise time as well as a faster settling time in comparison to only using PI control. Figure 34 shows the simulated graphs of the combination method with updated and non-updated PI parameters during the BB control phase.

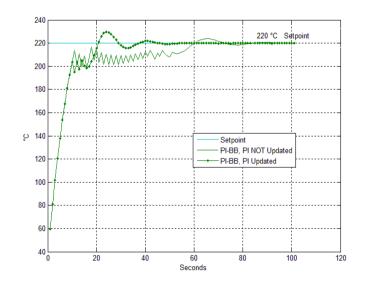


Figure 34 Proteus simulation of PI-BB control methods

3.5.1 Microcontroller program flow chart

According to Damij (2007) a flowchart is a good technique to represent the logical flow of a process that a program needs to follow. The microcontroller program was written in CCS C, a software package that uses the structure of C, but is optimised for microcontrollers. The program was developed for a PIC18F4220. Annexure B shows the program which was written in CCS C for a PIC microcontroller that follows the flowchart shown in figure 35.

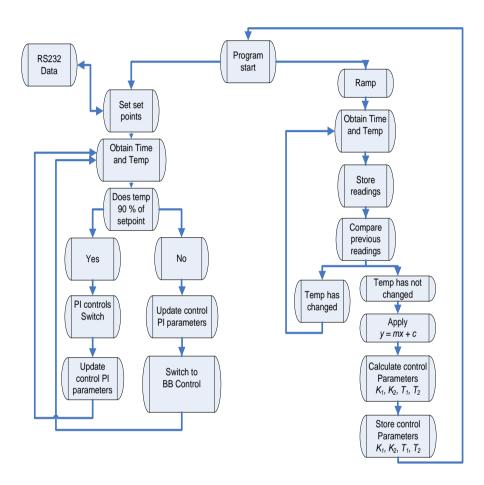


Figure 35 A flowchart outlining the functions of the CCS C software program

3.6 Design of a combination switch

As mentioned in Chapter 2, to counteract the disadvantages of a relay and of a TRIAC, a combination switch is used. Figure 36 shows this combination which encompasses a relay and a TRIAC to form a complete switching device.

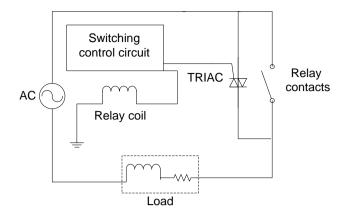


Figure 36 Combination switch

The switching control circuit is very important, as it will activate the two devices in such a way that only the advantages of each device are realized. The timing of the switching actions will be controlled by the microcontroller shown in figure 33.

3.6.1 Switch simulation data

The simulation of the combination switch was initially done using MATLAB Simulink. Figure 37 shows the design where two SCRs form the circuit of a TRIAC device. The control circuit will need to switch the relay and the TRIAC on simultaneously. The TRIAC is a solid-state device which will switch on faster, as the relay's coil must first be energised before enough magnetic energy is available to engage the contacts.

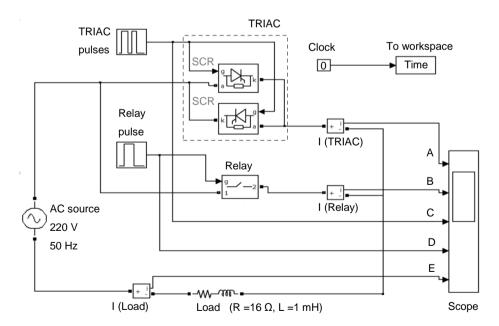


Figure 37 Simulation model of combination switch

This means that the load current will first flow through the TRIAC, thereby reducing the arcing of the relay contacts during switch on. As the relay is energised, contact bounce will still occur but with minimal arcing, as the load current flows through the TRIAC. Figure 38 show the results of the MATLAB simulation where current is seen to shift from the TRIAC to the relay during switch on. However, the load current remains constant during the switch on period.

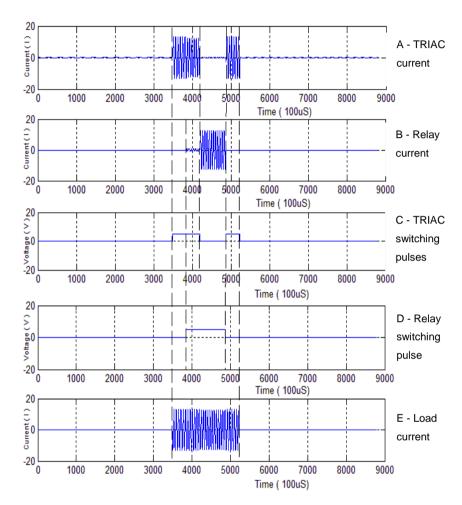


Figure 38 MATLAB simulated results of switching currents in relay, TRIAC and load

3.6.2 Switch practical results

The current through the TRIAC and relay was measured using an oscilloscope and two Fluke FC212 current probes, one measuring the relay contact current and the other the TRIAC current. Figure 39 shows when the contacts of the relay close (the resistance between them is less than that of the TRIAC's internal resistance R_f and R_r), current is transferred from the TRIAC to the relay contacts. As the contacts open the resistance between them increases so that it becomes more than that of the TRIAC, which causes

current to flow through the TRIAC. This occurs even during contact bounce, which is due to the mechanical forces between the relay contact plates. This transfer of current will continue until the contact bounce process settles, which was measured to be around 3 ms in this particular case.

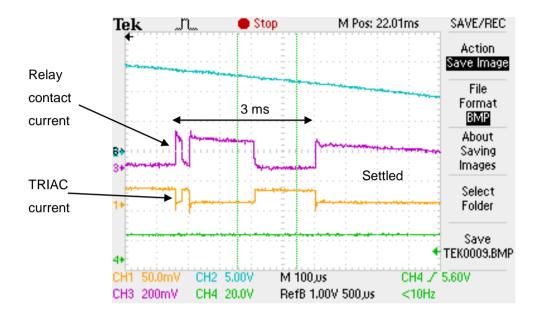


Figure 39 Measured current transfers between relay and TRIAC

Figure 40 indicates the relay switching settling time. The settling time will differ from relay to relay, due to different coils and voltages used by various manufacturers.

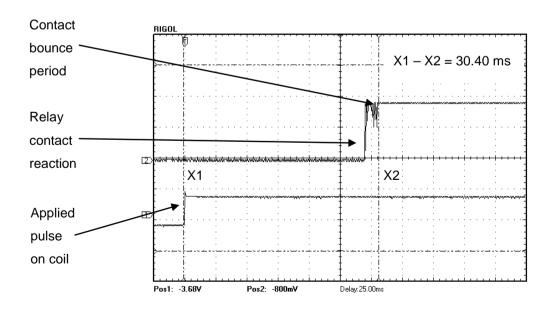


Figure 40 Relay settling duration

3.7 Summary

This chapter presented the analog system, oven characteristic curves, mathematical algorithm in the electrical environment, and a digital controller. The simulation and practical results of a combination switch in order to prolong longevity were also shown. The next chapter describes the controller and software which were developed to control the oven for a preset curing profile, along with relevant results.

Chapter 4 Experimental results

4.1 Introduction

This chapter will present the practical setup used to obtain results, the software interface developed for use in the curing profile control and the hardware prototypes that were developed. Results will be evaluated and experiments repeated to determine stability of control parameters during curing profile runs.

4.2 Practical setup and curing control results

A practical setup in the laboratory was done using a PIC3 development board, a PIC18F4220, switching board, sensor board, a 3 kW oven and developed software as mentioned in the previous chapter. Figure 41 shows the configuration of the setup used to obtain the results.

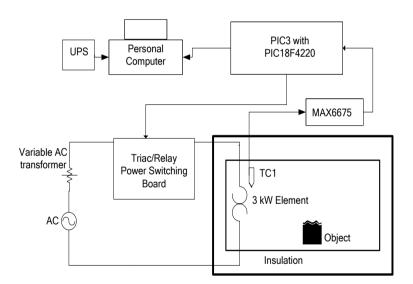


Figure 41 Practical setup of a 3 kW oven and switching board

A graphical user interface (GUI) was developed in Microsoft Visual Basic 6 (annexure A), which allows the user to enter and save a desired curing profile. This is vital in order to ensure that the same curing profile could be applied at a later stage to the same type of material. Figure 42 and figure 43 shows the capability of the developed software that allow the creating and storing facility of a specific curing profile.

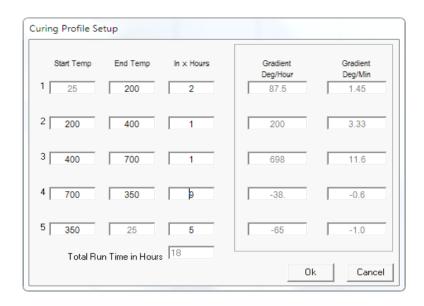


Figure 42 Curing profile creation capabilities of developed software

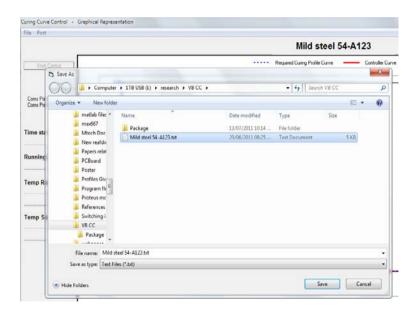


Figure 43 Curing profile saving capabilities of developed software

The blue dotted line in figure 44 represents the curing profile entered into the personal computer and acts as a visual representation of the curing profile required by the operator. The oven is initially set to full on. During this process, the PIC18F4220 microcontroller determines the control parameters as discussed using the Ziegler-Nichols method. Once this is done, the oven is ready to start the controlling process based on the predefined curing profile as in figure 44.

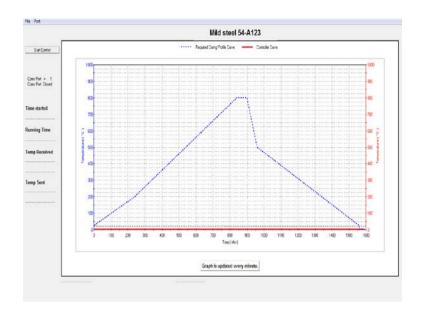


Figure 44 Curing profile saved in developed software

The time lapsed graph shown in figure 44, is updated every minute. The microcontroller updates the control parameters, taking an average of one hundred temperature readings, and determines the error with respect to the previous control parameters. This error is fed back into the control loop, ten times a minute, meaning that the control process has six seconds to read the temperature, average the readings, determine the new control parameters and apply it to the combination switch device.

4.3 Hardware

The software on the personal computer is used to provide a new set-point every minute that co-insides with the curing profile curve. It further visually shows the progress of the control process that is being applied to the oven with respect to the curing profile. The MAX6675 (annexure E) integrated circuit was used to convert the temperature readings from the thermocouple into a digital format to be used by the microcontroller. It has an accuracy of 0.5°C and a temperature range of -100°C to 2200°C. This device incorporates a coldjuction reference which is factory calibrated during the manufacturing process, thereby reducing the need for additional procedures and equipment during setup. Figure 45 shows the MAX6675 mounted on a prototype board for easy use with a common bread board.

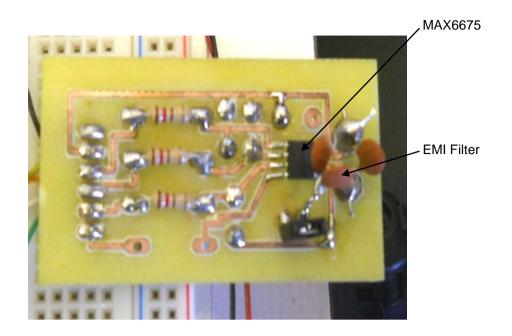


Figure 45 MAX6675 integrated circuit mounted on the prototype board

Data is sent via an I²C bus to the microcontroller and interpreted as a digital word. This is used to update the control parameters as mentioned earlier. The switching board can now be activated. Both TRIAC and relay are energised, but because of the time taken to fully energise the coil of the relay, a delay is experienced between these two devices. This is ideal as the TRIAC will conduct the current first, and then the relay when the contacts come to rest. The switching board is shown in figure 46. Connections to the oven's heating element are visible and the live wire is either closed or opened by either device.

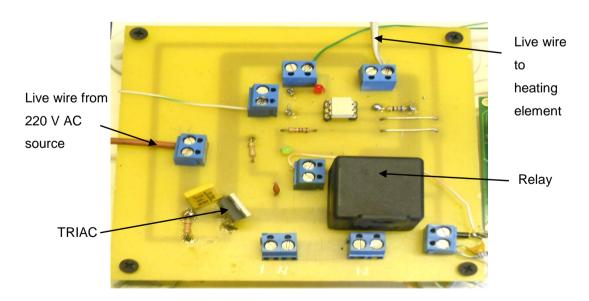


Figure 46 Combination power switch on the prototype board

Visual indications, in the form of two light emitting diodes (leds) are provided to show which device is activated. Combination switch activation was set to six seconds, in order to obtain the correct number of readings per minute as the processing time and communication between the temperature sensor and microcontroller is lengthy. Adapting the ON/OFF time of the switch in this way helped to achieve balance between activation time and delays due to processing.

Figure 47 shows a liquid crystal display (LCD) which is used to display the current set-point received from the personal computer and the average temperature measured during the processing time.



Figure 47 Operator information display unit

Figure 48 indicates the prototype controller (including microcontroller and a RS232 integrated circuit) which is used for communicating with the personal computer. The reason for using the RS232 communication protocol was due to the fact that it is included in the microcontroller, the PIC18F4220. This helps to reduce costs and minimize the total number of components required.

The control circuit uses a DC supply, but needs to switch an AC circuit. Therefore it was decided to isolate these two supply circuits. This was done by using an optocoupler driver (MOC3040 - see annexure F) which activated the TRIAC device. The relay provides its own isolation between the two circuits, as DC is applied to the coil, and AC to the relay contacts.

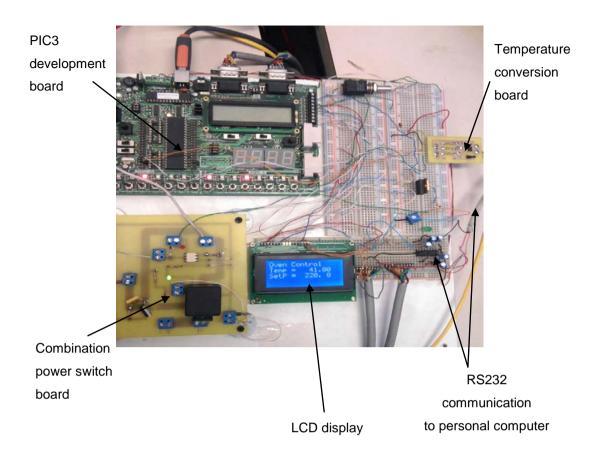


Figure 48 Prototype control unit with combination power switch

Calibration of the system was done using an infrared thermometer (LUTRON TM-2000). The thermometer uses an infrared beam to measure the amount of energy radiated by an object in order to determine its temperature. Figure 49 shows the infrared thermometer being used to measure the temperature of the thermocouple tip.



Figure 49 Infrared thermometer with laser target indicator, pointed at the thermocouple tip

Once calibration was complete the control parameters were automatically determined by the controller. A curing profile from the TSVUT was loaded in order to determine if the controller could follow it. Figure 50 shows the results of this process. A second curing profile was used to verify that the controller was following the loaded profile, as shown in figure 51.

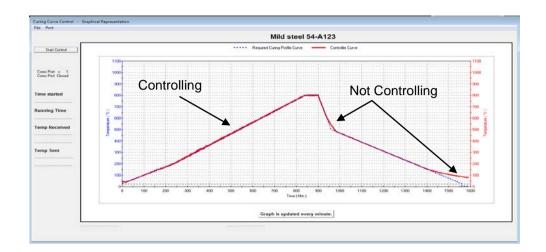


Figure 50 Predefined curing profile control results

From figure 50 and figure 51 it can be seen that the curing oven could not be controlled during certain times of the cooling process. This was found due to the fact that the rate of required cooling was outside the limits of the ovens normal cooling characteristics. The requested cooling profile was much faster than the natural cooling of the oven, and thus the controller could not follow it. As no additional changes to the oven were allowed, it was deemed acceptable. A second run was completed in order to determine the validity of the results (see figure 52).

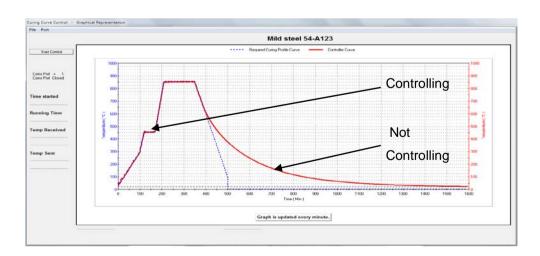


Figure 51 The second curing profile control results

The second run proved successful with a slight difference in the starting area of the profile, after which the controller effectively controlled the temperature as defined by the curing profile. Analysing a section of figure 52 using MATLAB indicates that there is still some overshoot and under-shoot, as suggested by the simulated results.



Figure 52 Predefined curing profile validity results

The over-shoot was found to be less than 5% over the duration of the curing profile. This was found to be valid for both curing profiles, including the second confirmation run of the initial curing profile. Figure 53 shows a sample of the maximum over- and under-shoot of an area during the curing profile.

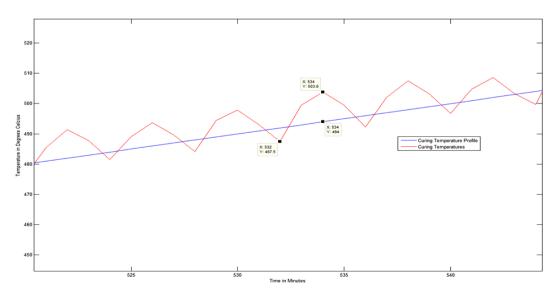


Figure 53 Over-shoot and under-shoot visualisation using MATLAB

The over-shoot was measured after 534 minutes and was found to be 503.8°C at the 494°C set-point. Using the previous reading at 532 minutes of 487.5°C an over-shoot and undershoot percentage can be calculated with equation (21) and equation (22).

%
$$Err = \frac{T_{measured} - T_{setpoint}}{T_{setpoint}} \times 100$$
 ... (21)
% $Err = \frac{503.8^{\circ}C - 494^{\circ}C}{494^{\circ}C} \times 100$
% $Err = 1.98\%$

A 1.98% over-shoot exits.

%
$$Err = \frac{T_{measured} - T_{setpoint}}{T_{setpoint}} \times 100$$
 ... (22)
% $Err = \frac{494^{\circ}C - 487.5^{\circ}C}{494^{\circ}C} \times 100$
% $Err = 1.31\%$

A 1.31% under-shoot exists.

4.4 Summary

This chapter considered the hardware and software design of the controller. It showed results of the controlling process after calibration was completed. The controlling process was repeated using different profiles in order to establish consistency and validity. The error obtained for under- and over-shoots were shown.

Chapter 5 presents some conclusions and discusses a few recommendations that have come to light.

Chapter 5 Conclusions and recommendations

5.1 Concluding comments

This chapter presents the conclusions reached with regard to the design and development of an automated temperature controller for curing ovens. The initial objectives will be compared to the outcomes of the project. Recommendations for future research will then be highlighted.

5.2 Conclusions attained from the study

The theoretical study revealed that the most suitable sensor available for measuring high temperatures is a type K-thermocouple. Cold compensation was needed in order to provide the correct reference for calculations of temperature and the MAX6675 was therefore chosen due to its accuracy, cost effectiveness and availability. It has the added benefit of being able to convert analogue temperature voltages into a digital form for processing by the microcontroller. The thermal conversion had to be calibrated and an infrared thermometer (LUTRON TM2000) was used to achieve this. Due to high inrush currents during switching, the MAX6675 was initially found to be unstable. A filtering device on the input of the MAX6675 was subsequently included, which allowed the sensor to provide stable readings in digital format to the microcontroller for processing.

The design and development of the prototype controller was accomplished by using a PIC18F4220 microcontroller. The controller software was written using CCS C, a C programming language used for PIC microcontrollers. A PIC3 development board (see figure 48) was used to embed the software code in the PIC18F4220. The code is provided in annexure B.

The switching unit proved successful in harnessing the advantages of a TRIAC and a relay by reducing heat, noise and contact burn. However, if a faster control is required, then other switching devices need be considered, as the relay has a delayed activation time.

5.3 Recommendations

The use of RTD's as sensory devices for low temperature applications (below 600°C), can be investigated in order to provide a simple interface to the microcontroller, thereby

eliminating the need for the MAX6675 device. This could reduce the cost of the overall development.

Different switching methods with respect to the technique used to drive the combination switch can be re-evaluated, in order to find another technique that will help to reduce transients during higher switching speeds.

Placing the sensory device inside the oven at different positions could help to ensure a better temperature representation of the heat inside the oven. This could lead to an enhanced representation of the object's temperature inside the oven.

5.4 Other applications

The designed controller could also be used for:

- Determining and controlling temperatures in fuel cells; and
- · Geyser control in solar geyser systems.

The combination switch could be used in power electronic applications, such as lighting and pump control.

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Annexure A Visual Basic 6 curing profile control program

```
Public dincnt As Integer
Public doutcnt As Integer
Public tmrcnt As Integer
Public tmrcnt1 As Integer
Public tmrcoms As Integer
Public Maxcnt As Integer
Private Sub Command1_Click()
Dim a As Integer
Exit Sub
If IblCommport.Caption < "1" Then
frmSplash.lblInfo.Caption = "Select Comm Port First ... "
frmSplash.Show
DoEvents
aa = Timer
bb = aa + 3
Do While aa < bb
DoEvents
aa = Timer
Loop
frmSplash.Hide
DoEvents
Exit Sub
End If
DoEvents
frmSplash.lblInfo.Caption = "Loading Curing Profile ... "
frmSplash.Show
DoEvents
DoEvents
Dim t As Double
Dim inc As Double
Maxcnt = 0
ghCurve.Visible = False
a = 0: inc = 1: t = 0
t = 25
                                     'Room Temperature
a = 1560 * 1.02
                                     ' Total number of minutes
ghCurve.ChartArea.Axes.Item(1).DataMax.Value = a
ghCurve.ChartArea.Axes.Item(1).DataMax = a
a = 0
For a = 1 To 1560
                                      'Intervals in minutes
If a = 1 Then inc = 0.729
If a = 241 Then inc = 1
If a = 841 Then inc = 0
If a = 901 Then inc = -5
If a = 961 Then inc = -0.792
```

```
t = t + inc
ghCurve.ChartGroups(1).Data.Y(1, a) = t
                                         ' Curing Plot
ghCurve.ChartGroups(2).Data.Y(1, a) = 2
                                          'Incoming Plot
If t > Maxcnt Then Maxcnt = t
Next a
ghCurve.ChartArea.Axes.Item(3).DataMax = Maxcnt + (Maxcnt * 0.05)
ghCurve.ChartArea.Axes.Item(2).DataMax = Maxcnt + (Maxcnt * 0.05)
ghCurve.Refresh
ghCurve.Visible = True
DoEvents
frmSplash.Hide
DoEvents
If IblCommport.Caption > "0" Then Command2.Enabled = True
End Sub
Private Sub Command2_Click()
If UCase(Command2.Caption) = "START CONTROL" Then
Command1.Enabled = False
Command2.Caption = "Stop Control"
MSComm1.CommPort = lblCommport.Caption
MSComm1.PortOpen = True
Label3.Caption = ".....": Label4.Caption = ".....": Label7.Caption = ".....": Label8.Caption =
".....": Label9.Caption = "....."
Label10.Caption = ".....": Label14.Caption = "....."
Label2.Caption = "Coms Port Open "
dincnt = 0
doutcnt = 0
tmrcnt = 0: tmrcnt1 = 0
stra = "25.00001"
Label3.Caption = stra
Label9.Caption = 1
MSComm1.Output = Trim(stra) & vbCr
tmrplot.Enabled = True
tmrComms.Enabled = True
tmrcoms = 0
Label14.Caption = Now
tmrplot_Timer
DoEvents
Exit Sub
End If
If UCase(Command2.Caption) = "STOP CONTROL" Then
Command1.Enabled = True
Command2.Caption = "Start Control"
stra = "02.00000"
DoEvents
Label3.Caption = ".....": Label4.Caption = "....": Label7.Caption = ".....": Label8.Caption =
".....": Label9.Caption = "....."
Label10.Caption = "....."
```

```
DoEvents
tmrComms.Enabled = False
tmrplot.Enabled = False
MSComm1.Output = Trim(stra) & vbCr
MSComm1.PortOpen = False
Label2.Caption = "Coms Port Closed"
dincnt = 1
doutcnt = 0
tmrcnt = 0: tmrcnt1 = 0
tmrcoms = 0
DoEvents
Exit Sub
End If
End Sub
Private Sub set-pointcomms()
End Sub
Private Sub Label16_Click()
End Sub
Private Sub mnuExit_Click(Index As Integer)
End
End Sub
Private Sub mnuLoad_Click()
CommonDialog1.Filter = "All Files (*.*)|*.*|Text Files (*.txt)|*.txt|Batch Files (*.bat)|*.bat" 'Specify default filter.
CommonDialog1.FilterIndex = 2 'Display the Open dialog box.
CommonDialog1.ShowOpen 'get a free file number
FileName = CommonDialog1.FileName
file1 = FreeFile 'open the file
If FileName = "" Then Exit Sub
DoEvents
frmSplash.lblInfo.Caption = "Loading Curing Profile ... "
frmSplash.Show
DoEvents
DoEvents
Maxcnt = 0
ghCurve.Visible = False
Open CommonDialog1.FileName For Input As file1 'Add some text to the file
Input #file1, Profilename
lblProfileName.Caption = Profilename
Input #file1, tempmax1
ghCurve.ChartArea.Axes.Item(3).DataMax = tempmax1
```

Input #file1, minmax ghCurve.ChartArea.Axes.Item(1).DataMax = minmax

ghCurve.ChartArea.Axes.Item(2).DataMax = tempmax2

Loopin:

Input #file1, i, cp, mcp

Input #file1, tempmax2

If i = "" Or i = " " Then GoTo loopout

```
ghCurve.ChartGroups(1).Data.Y(1, i) = Val(cp)
```

ghCurve.ChartGroups(2).Data.Y(1, i) = Val(mcp)

If Val(i) = Val(minmax) Then GoTo loopout

GoTo Loopin

loopout:

Close #file1

ghCurve.Refresh

ghCurve.Visible = True

DoEvents

frmSplash.Hide

DoEvents

If IblCommport.Caption > "0" Then Command2.Enabled = True

CommonDialog1.FileName = ""

FileName = ""

End Sub

Private Sub mnuNew_Click(Index As Integer)

frmCPsetup.Show

End Sub

Private Sub mnuPort_Click()

frmPort.Show

End Sub

Private Sub mnuPrint_Click()

Dim PrintDc As Long

Dim Y As Long

Dim iHeight As Long

Dim iWidth As Long

Dim iMargin As Long

Dim iSpace As Long

Dim qInfo As String

Dim qInfo1 As String

Dim qResult As Integer

'Make sure the user really wants to print the charts

qInfo = "Is it ok to print to the following printer?"

qInfo1 = Printer.DeviceName

qInfo = qInfo + Chr\$(13) + "'" + qInfo1 + "'"

qResult = MsgBox(qInfo, 4, "OK To Print?")

If qResult = 7 Then

Exit Sub

End If

Printer.Print "

Printer.Print "Curing Profile Name : " & IblProfileName.Caption 'Print header

Printer.Print " "

Printer.Print "

Printer.Print "Date Started : " & Label14.Caption
Printer.Print "Run Period : " & Label11.Caption

Printer.Print "

Printer.Print "Printed on : " & Now

```
Y = Printer.CurrentY + 10
                                    'Set position for line
Printer.Line (0, Y)-(Printer.ScaleWidth, Y) 'Draw a line across the page
iMargin = 1000 / Printer.TwipsPerPixelY + 400
iHeight = Printer.Height / Printer.TwipsPerPixelY - (iMargin * 2)
iWidth = Printer.Width / Printer.TwipsPerPixelX - iMargin
iSpace = 100 / Printer.TwipsPerPixelX
Result = ghCurve.DrawToDC(Printer.hDC, oc2dFormatEnhMetafile, oc2dScaleToFit, 0, Margin, iWidth, iHeight)
Printer.EndDoc
End Sub
Private Sub mnuReset_Click()
Dim a As Integer
DoEvents
frmSplash.lblInfo.Caption = "Resetting Measured Curing Profile ... "
frmSplash.Show
DoEvents
DoEvents
Maxcnt = 0
ghCurve.Visible = False
For a = 1 To Val(ghCurve.ChartArea.Axes.Item(1).DataMax.Value)
ghCurve.ChartGroups(2).Data.Y(1, a) = 2
                                             'Incoming Plot
Next a
ghCurve.Refresh
ghCurve.Visible = True
DoEvents
frmSplash.Hide
DoEvents
If IblCommport.Caption > "0" Then Command2.Enabled = True
End Sub
Private Sub mnuSave_Click(Index As Integer)
' Set filters.
CommonDialog1.Filter = "All Files (*.*)|*.*|Text Files (*.txt)|*.txt|Batch Files (*.bat)|*.bat" 'Specify default filter.
CommonDialog1.FilterIndex = 2 'Display the Open dialog box.
CommonDialog1.ShowSave ' get a free file number
FileName = CommonDialog1.FileName
file1 = FreeFile 'open the file
If FileName = "" Then Exit Sub
Open CommonDialog1.FileName For Output As file1 'Add some text to the file
Print #file1, lblProfileName.Caption
Print #file1, (Val(ghCurve.ChartArea.Axes.Item(3).DataMax) * 1.05)
Print #file1, (Val(ghCurve.ChartArea.Axes.Item(2).DataMax) * 1.05)
Print #file1, Val(ghCurve.ChartArea.Axes.Item(1).DataMax.Value)
For i = 1 To Val(ghCurve.ChartArea.Axes.Item(1).DataMax)
If i = 1561 Then
a = a
End If
```

Printer.Print "

If Val(ghCurve.ChartGroups(1).Data.Y(1, i)) < 2 Then ghCurve.ChartGroups(1).Data.Y(1, i) = 2

```
If Val(ghCurve.ChartGroups(2).Data.Y(1, i)) < 2 Then ghCurve.ChartGroups(2).Data.Y(1, i) = 2
If Val(ghCurve.ChartGroups(2).Data.Y(1, i)) = 1E+308 Then ghCurve.ChartGroups(2).Data.Y(1, i) = 2
Print #file1, i & vbTab & "," & ghCurve.ChartGroups(1).Data.Y(1, i) & vbTab & "," &
ghCurve.ChartGroups(2).Data.Y(1, i)
Next i
Close #file1
ghCurve.Refresh
ghCurve.Visible = True
DoEvents
DoEvents
CommonDialog1.FileName = ""
FileName = ""
End Sub
Private Sub MSComm1_oncomm()
Dim str As String
Dim stra As String
Dim bufin
Dim bufins
Select Case Me.MSComm1.CommEvent
Case comEvReceive
'This is used when data is received
stra = MSComm1.Input
Label4.Caption = stra
dincnt = dincnt + 1
Label8.Caption = dincnt
tmrcoms = 0
DoEvents
If dinct = 10000 Then dicnt = 2
MSComm1.InBufferCount = 0
End Select
End Sub
Private Sub tmrComms_Timer()
tmrcoms = tmrcoms + 1
TimetoAdd = TimeValue(Now) - TimeValue(Label14.Caption)
Label11.Caption = Format(TimetoAdd, "hh:mm:ss")
If tmrcoms = 57 Then
tmrComms.Enabled = False
tmrplot.Enabled = False
Command2_Click
frmSplash.lblInfo.Caption = "Comms Lost..... "
frmSplash.Show
DoEvents
aa = Timer
bb = aa + 2
Do While aa < bb
DoEvents 'Yield to other processes.
```

aa = Timer

```
Loop
frmSplash.Hide
Label3.Caption = ".....": Label4.Caption = "....": Label7.Caption = "....": Label8.Caption =
".....": Label9.Caption = "....."
Label10.Caption = "....."
DoEvents
DoEvents
Command2.SetFocus
End If
DoEvents
End Sub
Private Sub tmrplot_Timer()
Dim str, stra
TimetoAdd = TimeValue(Now) - TimeValue(Label14.Caption)
Label11.Caption = Format(TimetoAdd, "hh:mm:ss")
stra = Label4.Caption
Label10.Caption = Val(Label10.Caption) + 1
For i = 1 To 10
If Mid(stra, i, 1) = "," Then GoTo hop1
Next i
hop1:
str = Val(Mid(stra, 1, i - 1))
Label7.Caption = str
If Val(str) > 2 And Val(str) < 1101 Then
ghCurve.ChartGroups(2).Data.Y(1, Val(Label10.Caption)) = str
ghCurve.Refresh
DoEvents
End If
If Val(Label10.Caption) < 2 Then
If Val(Label7.Caption) < (Val(Label3.Caption) - 0.5) Then
Label10.Caption = Val(Label10.Caption) - 1
tmrcnt = 0
'GoTo jj
End If
End If
tmrcnt = tmrcnt + 1
If tmrcnt = 1 Then
If tmrcnt1 = 0 Then
str = Mid((ghCurve.ChartGroups(1).Data.Y(1, 1)), 1, 8)
str = Round(str, 2)
For u = 1 To Len(str)
rr = Mid(str, u, 1)
If rr = "." Then GoTo hop11
Next u
str = Val(str) + 0.00001
str = Val(str)
```

```
hop11:
stra = "00000001"
Mid(stra, 1, Len(str)) = str
Label3.Caption = stra
Label9.Caption = doutcnt
If Command2.Caption = "STOP CONTROL" Then
MSComm1.Output = Trim(stra) & vbCr
If Val(Label3.Caption) > Val(Label7.Caption) - 0.5 Then
Else
dincnt = 1: doutcnt = 1
Exit Sub
End If
End If
tmrcnt1 = 111
End If
End If
If tmrcnt = 1 Then
doutcnt = doutcnt + 1
If Command2.Enabled = True Then
If doutcnt + 1 > 9363 Then doutcnt = doutcnt - 10
str = Mid((ghCurve.ChartGroups(1).Data.Y(1, doutcnt)), 1, 8)
str = Round(str, 2)
For u = 1 To Len(str)
rr = Mid(str, u, 1)
If rr = "." Then GoTo hop12
Next u
str = Val(str) + 0.00001
str = Val(str)
hop12:
stra = "00000001"
Mid(stra, 1, Len(str)) = str
Label3.Caption = stra
Label9.Caption = doutcnt
MSComm1.Output = (stra) & vbCr
tmrcnt = 0: tmrcnt1 = 111
End If
End If
DoEvents
End Sub
```

Annexure B PIC18F4220 CCS C program

```
#include "main.h"
#include <stdlib.h>
#include <float.h>
#include "flex_lcd.c"
#include "max6675.c"
#include "PIparameterCalc.c"
char Received[9];
char msg[8];
int16 count,cnt1,cnt2,cnt3,dd;
float D,Td,T1,K,T,Kp,Ti,a,b,c;
float value1,value,mult,set-point,rkt,ekt,pkt,pktp,ukt,qkt,max,min,pkt_1,ekt_1;
#int_rda
void handle_data(void)
{
gets(received);
set-point=atof(received);
if (set-point<1)
//set-point=0;
}
else
rkt=set-point;
}
void main_on()
output_high(PIN_a1);
delay_ms(1);
output_high(PIN_a2);
delay_ms(30);
output_low(PIN_a1);
delay_ms(1);
Void main_off()
output_high(PIN_a1);
delay_ms(1);
output_low(PIN_a2);
delay_ms(30);
output_low(PIN_a1);
delay_ms(1);
void main()
```

```
WDT_ON;
 setup_wdt(WDT_2304MS);
setup_adc_ports(NO_ANALOGS|VSS_VDD);
setup_adc(ADC_OFF|ADC_TAD_MUL_0);
setup_psp(PSP_DISABLED);
setup_spi(SPI_SS_DISABLED);
setup_wdt(WDT_OFF);
setup_timer_0(RTCC_INTERNAL|RTCC_DIV_16|RTCC_8_bit);
setup_timer_1(T1_DISABLED);
setup_timer_2(T2_DISABLED,0,1);
setup_timer_3(T3_DISABLED|T3_DIV_BY_1);
setup_comparator(NC_NC_NC_NC);
setup_vref(FALSE);
enable_interrupts(INT_RDA);
enable_interrupts(GLOBAL);
setup_oscillator(OSC_8MHZ|OSC_TIMER1|OSC_31250|OSC_PLL_OFF);
cnt1=0;cnt2=0;cnt3=0;
lcd_init();
lcd_putc("\fGood day\n");
delay_ms(950);
lcd_putc("\fOven Control\n");
delay_ms(950);
lcd_gotoxy(1,2);
lcd_putc("Temp =
                     C");
T1=2400000;
                                    //Sample time in milisecondes
T=5000;
Td=1000;
K=680;
Kp=(0.9*T1)/(K*Td);
Ti=3.3*Td;
//D=0.5*Td;
a=Kp;
b=Kp*(T/Ti);
//c=(Kp*D)/T;
max=1000-60-49;
                           //maximum on time of heater in milisecondes, 60
milisecondes for the ON/OFF of the switch and 80 milliseconds for the comms
                                    //minimum off time of heater in milisecondes
min=1;
                                     // define set-point in Degrees C
set-point=2.00;
rkt=set-point;
pkt_1=0.0;
ekt_1=1.0;
count=0;
value=0;
dd=0;
do
{
```

```
hop1:
 value1=0; cnt3=0; value=0; mult=0.49995;
 restart_wdt();
for (cnt3=1;cnt3<=7;++cnt3)
 value=do_everything();
 value=value-49;
 value1=value1+value;
}
value=value1/7;
if ((value>-1) & (value<119)) { mult=0.5060;} // 0 Deg to 60 Deg
 if ((value>120) & (value<262)) { mult=0.4998;} // 60.25 Deg to 130 Deg
 if ((value>263) & (value<4003)) { mult=0.5029;} // 130.25 Deg to 190 Deg
 value=value*mult;
 value=value+10.00;
 sprintf(msg,"%8.2f",value);
                                                                                                                                                                                                                                                                                                                                                     // calculate error
               ekt=rkt-value;
                                                                                                                                                                                                                                                                                                                                                // calculate i term
               pkt=(b*ekt)+pkt_1;
                                                                                                                                                                                                                                                                                                                                                // calculate p term
               pktp=(a*ekt);
                                                                                                                                                                                                                                                                                                                                                // calculate d term
                   //qkt=c*(ekt-ekt_1);
                                                                                                                                                                                                                                                                                                                                                // calculate pid output
               ukt=pkt+pktp; //+qkt;
                                                                                                                                                                                                                                                                                                                                                // check min and max limits
               if (ukt>=max)
               pkt=pkt_1;
               ukt=max;
              }
               else if (ukt<=min)
          pkt=pkt_1;
          ukt=min;
                                                   LCD OUTPUT
     lcd\_gotoxy(8,2); lcd\_putc(msg[1]); msg[1] = ""; lcd\_gotoxy(9,2); lcd\_putc(msg[2]); msg[2] = ""; lcd\_gotoxy(9,2); lcd\_gotoxy(9,2
     lcd\_gotoxy(10,2); lcd\_putc(msg[3]); msg[3] = ""; lcd\_gotoxy(11,2); lcd\_putc(msg[4]); msg[4] = ""; lcd\_gotoxy(11,2); lcd\_gotoxy(11,
     lcd\_gotoxy(12,2); lcd\_putc(msg[5]); msg[5] = ""; lcd\_gotoxy(13,2); lcd\_putc(msg[6]); msg[6] = ""; lcd\_gotoxy(13,2); lcd
     lcd_gotoxy(14,2);lcd_putc(msg[7]);msg[7]="";
     sprintf(msg,"%8.2f",set-point);
     lcd_gotoxy(17,1);lcd_putc("SetP =
                                                                                                                                                                                                                                                                                                                                                C");
     \\ lcd\_gotoxy(24,1); \\ lcd\_putc(msg[1]); \\ msg[1] = ""; \\ lcd\_gotoxy(25,1); \\ lcd\_putc(msg[2]); \\ msg[2] = ""; \\ lcd\_gotoxy(25,1); \\ lcd\_gotoxy(2
     lcd\_gotoxy(26,1); lcd\_putc(msg[3]); msg[3] = ""; lcd\_gotoxy(27,1); lcd\_putc(msg[4]); msg[4] = ""; lcd\_gotoxy(27,1); lcd\_goto
     lcd_gotoxy(28,1);lcd_putc(msg[5]);msg[5]="";lcd_gotoxy(29,1);lcd_putc(msg[6]);msg[6]="";
```

```
lcd_gotoxy(30,1);lcd_putc(msg[7]);msg[7]="";
     LCD OUTPUT
      RS232 OUTPUT
printf("%08.2f",value);printf(", ");
//printf("%08.2f",value1);printf(", ");
printf("%09.2f",ekt);printf(", ");
printf("%09.2f",pkt);printf(", ");
printf("%09.0f",pktp);printf(", ");
printf("%09.0f",qkt);printf(", ");
printf("\%09.0f",ukt);printf("\ ,\ ");
printf("%09.0f",(max-ukt));printf(":");
//printf(" \r\n");
// RS232 OUTPUT
                                          // send control for heater switching
if (value<(rkt-3))
main_on();
cnt1=0;
delay_ms(1000);
cnt1=0;
main_off();
delay_ms(1);
cnt1=0;
if (value>(rkt+2))
main_off();
cnt1=0;
}
if (rkt<3)
output_low(PIN_a1);
output_low(PIN_a2);
cnt1=0;
}
if (ukt<1)
cnt1=0;
main_off();
goto hop2;
main_on();
cnt1=0;
delay_ms((int16)ukt);
cnt1=0;
main_off();
ay_ms((int16)max-(int16)ukt);
```

Include Files used by the controller

```
<main.h>
<stdlib.h>
<float.h>
<flex_lcd.c>
<max6675.c>
<PlparameterCalc.c>
```

Annexure C Turnitin originality report

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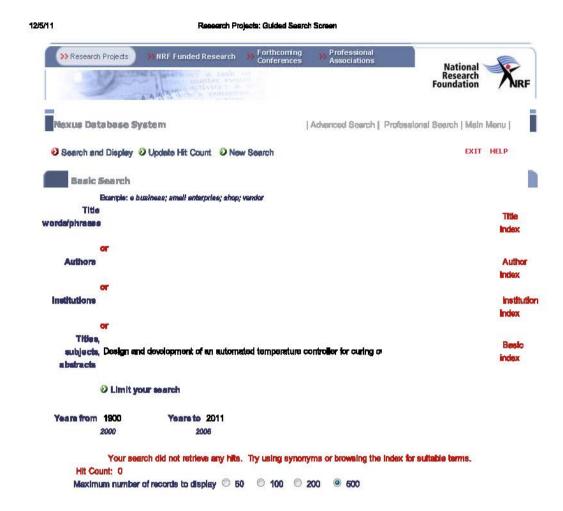
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paper text:

The temperature profile during the curing process of composite materials determines the final characteristics of the cured sample. The problem however of reproducing the same set of parameters with respect to different temperature settings for specific time periods makes for a control device to be present. Curing composite materials is normally done in an industrial oven. A heating element of low resistance generates heat which is then transferred to the material or object. This can be seen in figure 1 below, where heat from the heating element is transferred to the object inside the oven. Figure 1 Representation of electrical oven as a plant 2,2 Oven electrical equivalent model Heat is the process of energy transfer from one body or system to another due to a difference in temperature .Thermal energy can be defined as the energy of a body which increases with its temperature. Energy transfer by heat can occur between objects by radiation, conduction and/or convection (Kesidou and Duit 1993). Temperature can be used as a measure of the internal energy. Analysis of the heat flow in the oven can either be done by means of thermodynamics or by using and electrical analogy of the heat flow path. Heat flow can be modelled by an analogy to an electrical circuit seen in table 1, where heat flow is represented by current, temperatures are represented by voltages, heat sources are represented by constant current sources, thermal resistances are represented by resistors and thermal capacitances by capacitors . Table 1 Equivalence between thermal and electrical entities Thermal quantity Unit Electrical quantity Unit P, Heat flow, power W I, Current flow A Δθ, Temperature difference K V, Voltage V Rth, Thermal resistance K/W R, Electrical resistance Ω Cth, Thermal mass, capacitance J/K C, Electrical Capacitance F πth=Rth*Cth, Thermal RC constant s T = R*C, Electrical RC constant s This can be seen in figure 2 were R1 represents the thermal resistance between the heating element and the oven, R2 represents the resistance between the oven and the environment, C1 represents the heat capacity of the element, C2 represents the heat capacity of the oven, 8 a represents the ambient temperature of the environment, W represents the power dissipated in the heating elements, θv the oven temperature and θh represents the heating element temperature. The capacitor C1 can be neglected from the equivalent diagram as the capacity of the element to store heat is very little in comparison to that of the oven capacity to store heat. Figure 2 Electrical equivalent of thermal oven Therefore figure 3 shows the diagram that can be used as the electrical equivalent of a thermal oven with input voltage vi(t) input current i(t) and output voltage vo(t). Figure 3 Electrical equivalent of thermal oven, simplified Finding the transfer function of this circuit now becomes simplified, by applying basic electrical principals of current and voltage rules as well as the relationships between voltage, current and impedance as can be seen in table 2. Table 2 Voltage and current and current and voltage relationships, summarized The time domain equation can be found by applying Kirchhoff's voltage law: (1) Now by using table two the current flowing through the capacitor can be written (2) By substituting (2) in (1) all terms in

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Annexure D NRF Nexus title search report



Annexure E MAX6675 datasheet

19-2235- Rev 1-3/02

NIXIN

Cold-Junction-Compensated K-Thermocoupleto-Digital Converter (0°C to +1024°C)

General Description

The MAX6675 performs cold-junction compensation and digitizes the signal from a type-K thermocouple. The data is output in a 12-bit resolution, SPI™-compatible, read-only format.

This converter resolves temperatures to 0.25°C, allows readings as high as +1024°C, and exhibits thermocouple accuracy of 8LSBs for temperatures ranging from

The MAX6675 is available in a small, 8-pin SO package.

Features

- ♦ Direct Digital Conversion of Type -K Thermocouple Output
- ♦ Cold-Junction Compensation
- ♦ Simple SPI-Compatible Serial Interface
- ♦ 12-Bit, 0.25°C Resolution
- ♦ Open Thermocouple Detection

Ordering Information

5 SCK

PART	TEMP RANGE	PIN-PACKAGE		
MAX6675ISA	-20°C to +85°C	8 SO		

Applications

Industrial Appliances HVAC Automotive

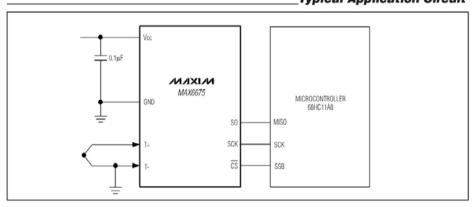
Pin Configuration TOP VIEW GND 1 8 N.C. T- 2 MIXNN 7 S0 MAX6675 T+ 3 6 CS

VCC 4

SPI is a trademark of Motorola, Inc.

Typical Application Circuit

so



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For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

MAX66/5

Cold-Junction-Compensated K-Thermocoupleto-Digital Converter (0°C to +1024°C)

ABSOLUTE MAXIMUM RATINGS

Supply Voltage (VCC to GND)	0.3V to +6V
SO, SCK, CS, T-, T+ to GND	0.3V to V _{CC} + 0.3V
SO Current	50mA
ESD Protection (Human Body Model)	±2000V
Continuous Power Dissipation (TA = +70°	°C)
8-Pin SO (derate 5.88mW/°C above +7	70°C) 471mW
Operating Temperature Range	20°C to +85°C

Storage Temperature Range Junction Temperature	
SO Package	+150-0
Vapor Phase (60s)	
Infrared (15s)	
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +3.0 \text{V to } +5.5 \text{V}, T_A = -20 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}, \text{ unless otherwise noted. Typical values specified at } +25 ^{\circ}\text{C.})$ (Note 1)

PARAMETER	SYMBOL	CONE	MIN	TYP	MAX	UNITS		
		TTHERMOCOUPLE = +7	00°C,	V _{CC} = +3.3V	-5		+5	
		T _A = +25°C (Note 2)	T _A = +25°C (Note 2) V _{CC}		-6		+6]
		TTHERMOCOUPLE = 0°0	C to	V _{CC} = +3.3V	-8		+8]
Temperature Error		+700°C, TA = +25°C (Note 2)	Vcc = +5V	-9		+9	LSB
		TTHERMOCOUPLE = +7 to +1000°C, TA = +25		V _{CC} = +3.3V	-17		+17	
		(Note 2)		Vcc = +5V	-19		+19	
Thermocouple Conversion Constant						10.25		μV/LSB
Cold-Junction		T _A = -20°C to +85°C	Vcc =	+3.3V	-3.0		+3.0	°C
Compensation Error		(Note 2)	Vcc =	+5V	-3.0		+3.0	
Resolution						0.25		°C
Thermocouple Input Impedance						60		kΩ
Supply Voltage	Vcc				3.0		5.5	V
Supply Current	lcc					0.7	1.5	mA
Power-On Reset Threshold		V _{CC} rising			1	2	2.5	V
Power-On Reset Hysteresis						50		mV
Conversion Time		(Note 2)				0.17	0.22	s
SERIAL INTERFACE								
Input Low Voltage	V _{IL}						0.3 x Vcc	٧
Input High Voltage	VIH				0.7 x Vcc			٧
Input Leakage Current	ILEAK	V _{IN} = GND or V _{CC}		•			±5	μA
Input Capacitance	CIN					5		pF

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ELECTRICAL CHARACTERISTICS (continued)

(VCC = +3.0V to +5.5V, TA = -20°C to +85°C, unless otherwise noted. Typical values specified at +25°C.) (Note 1)

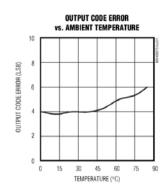
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Output High Voltage	V _{OH}	ISOURCE = 1.6mA	V _{CC} - 0.4			٧
Output Low Voltage	VOL	ISINK = 1.6mA			0.4	٧
TIMING						
Serial Clock Frequency	fscL				4.3	MHz
SCK Pulse High Width	tcH		100			ns
SCK Pulse Low Width	tCL		100			ns
CSB Fall to SCK Rise	tcss	C _L = 10pF	100			ns
CSB Fall to Output Enable	tDV	C _L = 10pF			100	ns
CSB Rise to Output Disable	tTR	C _L = 10pF			100	ns
SCK Fall to Output Data Valid	tpo	C _L = 10pF			100	ns

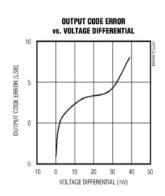
Note 1: All specifications are 100% tested at TA = +25°C. Specification limits over temperature (TA = TMIN to TMAX) are guaranteed by design and characterization, not production tested.

Note 2: Guaranteed by design. Not production tested.

Typical Operating Characteristics

(VCC = +3.3V, T_A = +25°C, unless otherwise noted.)





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MAX66/5

Cold-Junction-Compensated K-Thermocoupleto-Digital Converter (0°C to +1024°C)

Pin Description

		_
PIN	NAME	FUNCTION
1	GND	Ground
2 T-		Alumel Lead of Type-K Thermocouple. Should be connected to ground externally.
3	T+	Chromel Lead of Type-K Thermocouple
4	Vcc	Positive Supply. Bypass with a 0.1µF capacitor to GND.
5	SCK	Serial Clock Input
6	CS	Chip Select. Set $\overline{\text{CS}}$ low to enable the serial interface.
7	SO	Serial Data Output
8	N.C.	No Connection

Detailed Description

The MAX6675 is a sophisticated thermocouple-to-digital converter with a built-in 12-bit analog-to-digital converter (ADC). The MAX6675 also contains cold-junction compensation sensing and correction, a digital controller, an SPI-compatible interface, and associated control logic.

The MAX6675 is designed to work in conjunction with an external microcontroller (μ C) or other intelligence in thermostatic, process-control, or monitoring applications.

Temperature Conversion

The MAX6675 includes signal-conditioning hardware to convert the thermocouple's signal into a voltage compatible with the input channels of the ADC. The T+ and T-inputs connect to internal circuitry that reduces the introduction of noise errors from the thermocouple wires.

Before converting the thermoelectric voltages into equivalent temperature values, it is necessary to compensate for the difference between the thermocouple cold-junction side (MAX6675 ambient temperature) and a 0°C virtual reference. For a type-K thermocouple, the voltage changes by 41µV/°C, which approximates the thermocouple characteristic with the following linear equation:

 $V_{OUT} = (41\mu V / ^{\circ}C) \times (T_{R} - T_{AMB})$

Where:

VOUT is the thermocouple output voltage (µV).

 $T_{\mbox{\scriptsize R}}$ is the temperature of the remote thermocouple junction (°C).

TAMB is the ambient temperature (°C).

Cold-Junction Compensation

The function of the thermocouple is to sense a difference in temperature between two ends of the thermocouple wires. The thermocouple's hot junction can be read from 0°C to +1023.75°C. The cold end (ambient temperature of the board on which the MAX6675 is mounted) can only range from -20°C to +85°C. While the temperature at the cold end fluctuates, the MAX6675 continues to accurately sense the temperature difference at the opposite end.

The MAX6675 senses and corrects for the changes in the ambient temperature with cold-junction compensation. The device converts the ambient temperature reading into a voltage using a temperature-sensing diode. To make the actual thermocouple temperature measurement, the MAX6675 measures the voltage from the thermocouple's output and from the sensing diode. The device's internal circuitry passes the diode's voltage (sensing ambient temperature) and thermocouple voltage (sensing remote temperature minus ambient temperature) to the conversion function stored in the ADC to calculate the thermocouple's hot-junction temperature.

Optimal performance from the MAX6675 is achieved when the thermocouple cold junction and the MAX6675 are at the same temperature. Avoid placing heat-generating devices or components near the MAX6675 because this may produce cold-junction-related errors.

Digitization

The ADC adds the cold-junction diode measurement with the amplified thermocouple voltage and reads out the 12-bit result onto the SO pin. A sequence of all zeros means the thermocouple reading is 0°C. A sequence of all ones means the thermocouple reading is +1023.75°C.

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Applications Information

Serial Interface

The Typical Application Circuit shows the MAX6675 interfaced with a microcontroller. In this example, the MAX6675 processes the reading from the thermocouple and transmits the data through a serial interface. Force $\overline{\text{CS}}$ low and apply a clock signal at SCK to read the results at SO. Forcing $\overline{\text{CS}}$ low immediately stops any conversion process. Initiate a new conversion process by forcing $\overline{\text{CS}}$ high.

Force $\overline{\text{CS}}$ low to output the first bit on the SO pin. A complete serial interface read requires 16 clock cycles. Read the 16 output bits on the falling edge of the clock. The first bit, D15, is a dummy sign bit and is always zero. Bits D14–D3 contain the converted temperature in the order of MSB to LSB. Bit D2 is normally low and goes high when the thermocouple input is open. D1 is low to provide a device ID for the MAX6675 and bit D0 is three-state.

Figure 1a is the serial interface protocol and Figure 1b shows the serial interface timing. Figure 2 is the SO output

Open Thermocouple

Bit D2 is normally low and goes high if the thermocouple input is open. In order to allow the operation of the open thermocouple detector, T- must be grounded. Make the ground connection as close to the GND pin as possible.

Noise Considerations

The accuracy of the MAX6675 is susceptible to powersupply coupled noise. The effects of power-supply noise can be minimized by placing a 0.1µF ceramic bypass capacitor close to the supply pin of the device.

Thermal Considerations

Self-heating degrades the temperature measurement accuracy of the MAX6675 in some applications. The magnitude of the temperature errors depends on the thermal conductivity of the MAX6675 package, the

mounting technique, and the effects of airflow. Use a large ground plane to improve the temperature measurement accuracy of the MAX6675.

The accuracy of a thermocouple system can also be improved by following these precautions:

- Use the largest wire possible that does not shunt heat away from the measurement area.
- If small wire is required, use it only in the region of the measurement and use extension wire for the region with no temperature gradient.
- Avoid mechanical stress and vibration, which could strain the wires
- When using long thermocouple wires, use a twistedpair extension wire.
- · Avoid steep temperature gradients.
- Try to use the thermocouple wire well within its temperature rating.
- Use the proper sheathing material in hostile environments to protect the thermocouple wire.
- Use extension wire only at low temperatures and only in regions of small gradients.
- Keep an event log and a continuous record of thermocouple resistance.

Reducing Effects of Pick-Up Noise

The input amplifier (A1) is a low-noise amplifier designed to enable high-precision input sensing. Keep the thermocouple and connecting wires away from electrical noise sources.

Chip Information

TRANSISTOR COUNT: 6720 PROCESS: BICMOS

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MAX66/5

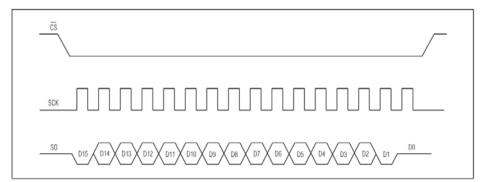


Figure 1a. Serial Interface Protocol

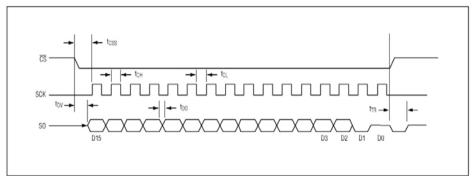
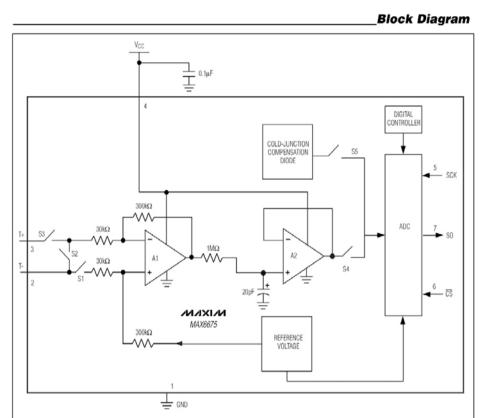


Figure 1b. Serial Interface Timing

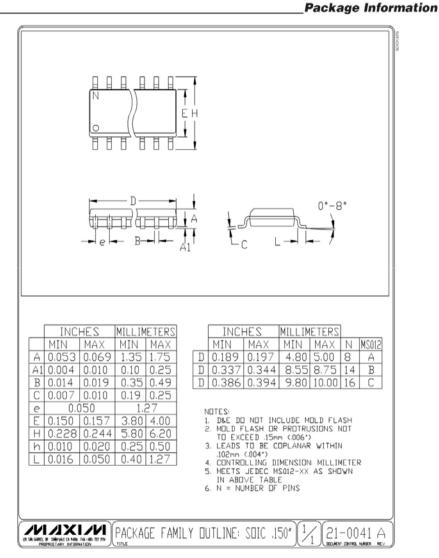
BIT	DUMMY SIGN BIT		12-BIT TEMPERATURE READING					THERMOCOUPLE INPUT	DEVICE ID	STATE						
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	0	MSB											LSB		0	Three- state

Figure 2. SO Output

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Annexure F MOC3040 datasheet



ZERO VOLTAGE CROSSING OPTICALLY ISOLATED TRIAC DRIVER

This device consists of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon detector performing the function of a Zero Voltage Crossing bilateral triac driver.

They are designed for use with a triac in the interface of logic systems to equipment powered from 220 Vac lines, such as solid-state relays, industrial controls, motors, solenoids and consumer appliances, etc.

- Simplifies Logic Control of 220 Vac Power
- Zero Voltage Crossing
- High Breakdown Voltage: VDRM = 400 V Min
- High Isolation Voltage: V_{ISO} = 7500 V Min
- Small, Economical, 6-Pin DIP Package
- Same Pin Configuration as MOC3020/3021
- UL Recognized, File No. E54915
- dv/dt of 100 V/μs Typ

MAXIMUM RATINGS (TA = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
INFRARED EMITTING DIODE MAXIMU	M RATINGS		
Reverse Voltage	V _R	6.0	Volts
Forward Current - Continuous	1 _F	50	mA
Total Power Dissipation @ T _A = 25°C Negligible Power in Output Driver	PD	120	mW
Derate above 25°C		1.33	mW/°C
OUTPUT DRIVER MAXIMUM RATINGS			
Off-State Output Terminal Voltage	V _{DRM}	400	Volts
On-State RMS Current TA = 25°C	¹T(RMS)	100	mA
(Full Cycle , 50 to 60 Hz) T _A = 70°C		50	mA
Peak Nonrepetitive Surge Current (PW = 10 ms)	TSM	1.2	A
Total Power Dissipation @ T _A = 25°C	PD	300	mW
Derate above 25°C	1 - 1	4.0	mW/°C

•	ťΟ	TAL	DE	VICE	MAX	MUMD	RAT	INGS

Isolation Surge Voltage (1) (Peak ac Voltage, 60 Hz, 5 Second Duration)	Viso	7500	Vac
Total Power Dissipation @ T _A = 25°C Derate above 25°C	PD	330 4.4	mW/°C
Junction Temperature Range	TJ	-40 to +100	°C
Ambient Operating Temperature Range	TA	-40 to +70	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C
Soldering Temperature (10 s)		260	°C

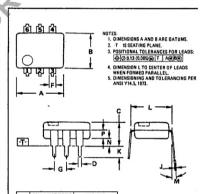
(1) Isolation surge voltage, VISO, is an internal device dielectric breakdown rating.

MOC3040 MOC3041

OPTO COUPLER / ISOLATOR ZERO CROSSING TRIAC DRIVER

400 VOLTS





	MILLI	METERS	INC	HEŞ			
DIM	MIN	MAX	MIN	MAX	1		
A	8.13	8.89	0.320	0.350	1		
В	6.10	6.60	0.240	0.260	1		
C	2.92	5.08	0.115	0.200	STYLE		0.00000
D	0.41	0.51	0.016	0.020	PIN	١.	ANODE
F	1.02	1.78	0.040	0.070	1	2.	CATHODE
G	2.54	BSC	0.10	OO BSC	1	3.	NC
J	0.20	0.30	0.008	0.012	1	4.	MAIN TERMINAL
K	2.54	3.81	0.100	0.150	1	5.	SUBSTRATE
L	7.62	BSC	0.30	O BSC	1	6.	MAIN TERMINAL
M	Oo	150	00	150	1		
N	0.38	2.54	0.015	0.100	1		
P	1.27	2.03	0.050	0.080	1		

CASE 730A-01

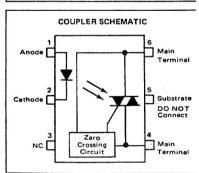
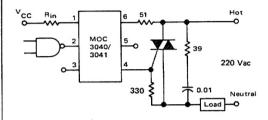


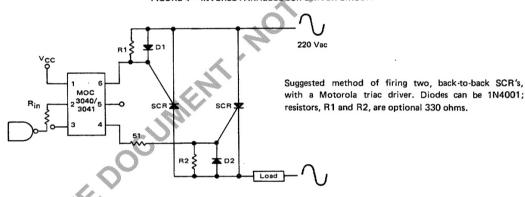
FIGURE 3 - HOT-LINE SWITCHING APPLICATION CIRCUIT



Typical circuit for use when hot line switching is required. In this circuit the "hot" side of the line is switched and the load connected to the cold or neutral side. The load may be connected to either the neutral or hot line.

Rin is calculated so that IF is equal to the rated IFT of the part, 15 mA for the MOC3041 or 30 mA for the MOC3040. The 39 ohm resistor and 0.01 µF capacitor are for snubbing of the triac and may or may not be necessary depending upon the particular triac and load

FIGURE 4 - INVERSE-PARALLEL SCR DRIVER CIRCUIT



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MOTOROLA Semiconductor Products Inc. -

ELECTRICAL	. CHARACTERISTICS	TA = 25°C	unless otherwise noted)
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Characteristic	Symbol	Min	Тур	Max	Unit
LED CHARACTERISTICS					
Reverse Leakage Current (V _R = 6.0 V)	IR.	-	0.05	100	μА
Forward Voltage (I _F = 30 mA)	VF	-	1.3	1.5	Volts
DETECTOR CHARACTERISTICS (IF = 0 unless otherwise noted)				1	A.
Peak Blocking Current, Either Direction (Rated V _{DRM} , Note 1)	IDRM1	_	2.0	100	nA
Peak On-State Voltage, Either Direction (I _{TM} = 100 mA Peak)	VTM	-	1.8	3.0	Volts
Critical Rate of Rise of Off-State Voltage	dv/dt	_	100) -	V/µs

COUPLED CHARACTERISTICS

LED Trigger Current, Current Required to Latch Output	!	IFT	1/6	(A)		mA
(Main Terminal Voltage = 3.0 V, Note 2)	MOC3040		(- 1)		30	
	MOC3041		4	-	15	
Holding Current, Either Direction		¹H_	Jane -	200	1	μА

ZERO CROSSING CHARACTERISTICS

Inhibit Voltage (I F = Rated I FT, MT1-MT2 Voltage above which device will not trigger.)	.0	VIH	-	15	40	Volts
Leakage in Inhibited State (I _F = Rated I _{FT} , Rated V _{DRM} , Off State)	13	IDRM2	-	100	300	μА

Note 1. Test voltage must be applied within dv/dt rating.

2. All devices are guaranteed to trigger at an I_F value less than or equal to max I_FT. Therefore, recommended operating I_F lies between max I_FT (30 mA for MOC3040, 15 mA for MOC3041) and absolute max I_F (50 mA).

TYPICAL ELECTRICAL CHARACTERISTICS

FIGURE 1 - ON-STATE CHARACTERISTICS

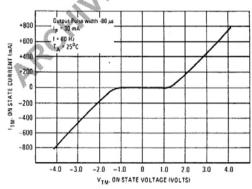
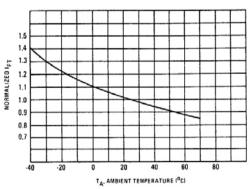


FIGURE 2 — TRIGGER CURRENT versus TEMPERATURE



MOTOROLA Semiconductor Products Inc.

Annexure G Type K-thermocouple datasheet



MAXIMUM TEMPERAT Thermocouple Grade - 328 to 2282°F - 200 to 1250°C Extension Grade 32 to 392°F 0 to 200°C

0 to 200°C
LIMITS OF ERROR
(whichever is greater)
Standard: 2.2°C or 0.75% Above 0°C
2.2°C or 2.0% Below 0°C
Special: 1.1°C or 0.4%
COMMENTS, BARE WIRE ENVIRONMENT:

COMMENTS, BAKE WIKE ENVIRONME Clean Oxidizing and Inert: Limited Use in Vacuum or Reducing; Wide Temperature Range: Most Popular Calibration TEMPERATURE IN DEGREES °F REFERENCE JUNCTION AT 32°F



Extension Grade

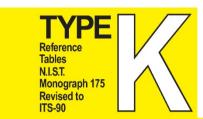
Revised Thermocouple Reference Tables





										Ther	moek	ectric \	/oltage	in Mil	livolts										
°F	-10	-9	-8	-7	-6	-5	-4	-3	-2	-1	0	*F	1 °F	0	1	2	3	4	5	6	7	8	9	10	*F
													100				1.589		1.635	1.657					100
													110				1.817								110
													120				2.046								130
450							-6.458	-6.457	6.457	-6.456	-6.456	-450	140				2.506								140
										2.11		711	1000			1222									
	6.446												150 160				2.736								160
	6.431												170				3.197								170
-410	6.409	-6.406	-6.404	6.401	-6.398	-6.395	-6.392	-6.389	-6.386	-6.383	-6.380	410	180				3.428								180
400	6.380	-6.377	-6.373	-6.370	6.366	-6.363	-6.359	-6.355	-6.352	6.348	-6.344	400	190	3.590	3.613	3.636	3.659	3.682	3.705	3.728	3.751	3.774	3.797	3.820	190
390	6.344	.6 340	6.336	.6 332	E 328	E 323	6 319	.6 315	.6 330	.6.306	6 701	.390	200	3.820	3.843	3.866	3.889	3 912	3 035	3 948	3 981	4.004	4 027	4.050	200
	-6.301											-380	210	4.050		4.096					4.211		4.257	4.280	210
-370				6.235						6.201		370	220	4.280			4.349								220
-360 -350	6.195			6.177								-360 -350	230 240	4.509			4.578 4.806								230
3.00	4.133	0.120	10.110	0.113	u, rou	0.055	U.0/32	11,000	u.uru	u.ur i	0.004	330	2.412	4.7.30	4.7607	4.703	4.0001	4,02.0	4.002	4,014	4.601	4.324	4.544	4,500	240
	-6.064											-340	250	4.965			5.034								250
	-5.989											-330	260				5.260								260
	-5.908 -5.822												270 280				5.712							5,644	270
	-5.730												290	5.869			5.937								290
							39/201					CUC	1222	1222		-222	12000	7.55.50	1222	10000	2222	20020	10,500	0000	5557
	5.632												300 310	6.094			6.161			6.228		6.272	6.295		300
	-5.421												320				6.607								320
-260	-5.308	-5.296	-5.285	-5.273	-5.261	-5.250	-5.238	-5.226	-5.214	-5.202	-5.190	-260	330	6.763	6.785	6.807	6.829	6.852	6.874	6.896	6.918	6.941	6.963	6.985	330
-250	-5.190	-5.178	-5.166	-5.153	-5.141	-5.129	-5.117	-5.104	-5.092	-5.079	-5.067	-250	340	6.985	7.007	7.029	7.052	7.074	7.096	7.118	7.140	7.163	7.185	7.207	340
240	-5.067	5.054	5.042	.5.000	5.016	.5 M3	4 901	4 079	A 064	4.052	4 030	-240	350	7 207	7 220	2 251	7 277	7 206	7 319	7 340	7 762	7 204	7 407	7,429	350
	4 939												360	7.429		7.473		7.517		7.562	7.584		7.628		360
	4.806												370	7.650		7.695		7.739		7.783					370
	4.669												380	7.872		7.917		7.961				8.050			380
-200	4.527	-4.513	-4.498	-4.484	-4.469	-4.455	-4.440	-4.425	4.411	-4.396	-4.381	-200	390	8.094	8,116	8,138	8.161	8.183	8.205	8.227	8.250	8,212	8.294	8.316	390
-190	4.381	4.366	4.351	4.336	4.321	-4.306	-4.291	4.276	-4.261	4.246	-4.231	190	400	8.316	8.338	8.361	8.383	8.405	8.427	8.450	8.472	8.494	8.516	8.539	400
	4.231												410				8.605								410
	-4.076 -3.917												420 430	8.761	8.784	8.806	8.828	8.851	8.873	8.895	8.918	8,940	8.962	8.985	420
	3.754												440												440
													5,400												
	3.587												45D											9.657	
	-3.417 -3.243												460 470											9,882	
	3.065																							10.334	
-100	2.884	2.865	-2.847	-2.829	2.810	2.792	-2.773	-2.755	2.736	2.718	2.699	-100	490	10.334	10.357	10.380	10.402	10.425	10.448	10.471	10.493	10.516	10.539	10.561	490
.90	-2.699	-2 680	.2 662	2643	.2 624	2.605	.2 597	.2 960	2 549	-2 530	2511	-90	Snn	10.561	10.584	10.607	10.629	10.652	10 675	10.698	10.720	10.743	10 266	10.789	500
	-2.511											-80					10.857								510
	2.320											70					11.085								520
	-2.126											-60 -50					11.313							11.474	530 540
-30	-1.329	-1.303	-1.009	-1.009	-1.000	-1.030	-1.010	-1.790	-1.770	-1.749	-1.729	-30	1000												340
	-1.729											-40					11.772								550
	-1.527											-30												12.163	560
	-1.322											-20												12.393	570
	0.905											0					12.693								590
													507.00%												
10	0.692	0.671		0.628								10					12.924								610
20	-0.478											20					13.155							13.549	
30	-0.044											30	630	13,549	13.573	13.596	13.619	13.642	13.665	13.689	13.712	13.735	13.758	13.782	630
40	0.176	0.198	0.220	0.242	0.264	0.286	0.308	0.330	0.353	0.375	0.397	40	640	13.782	13.805	13.828	13.851	13.874	13,898	13,921	13.944	13.967	13.991	14.014	640
50	0.397	0.419	0.441	0.463	0.486	0.500	0.530	0.552	0.575	0.597	0.619	50	650	14.014	14.037	14.060	14.084	14.107	14.130	14.154	14.177	14.200	14.223	14.247	650
60				0.686		0.731				0.821		60	660	14.247	14.270	14.293	14.316	14.340	14.363	14.386	14.410	14.433	14.456	14.479	
70	0.843		0.888			0.955			1.023	1.045		70					14.549								670
80	1.068	1.090	1.113	1.136		1.181		1.226	1.249	1.271	1.294	80 90					14.783 15.016								680
40	1.294	1.316	1.339	1.305	1.384	1.407	1.430	1.453	1.475	1.496	1.521	90	030	14.946	14.509	14.993	15.016	15.039	15.063	15.006	15.109	13.133	15.156	15.179	990
°F	0	1	2	3	4	5	6	7	8	9	10	*F.	°F.	0	1	2	3	- 4	5	6	7	8	9	10	*F

Revised Thermocouple Reference Tables





Nickel-Chromium vs. Nickel-Aluminum

Extension Grade



MAXIMUM TEMPERATURE RANGE

MAXIMUM TEMPERATURE RANGE
Thermocouple Grade
- 328 to 2282°F
- 200 to 1250°C
Extension Grade
32 to 392°F
0 to 200°C
LIMITS OF ERROR
(whichever is greater)
Standard: 2.2°C or 0.75% Above 0°C
2.2°C or 2.0% Below 0°C
Special: 1.1°C or 0.4%
COMMENTS, BARE WIRE ENVIRONMENT:
Clean Oxidizing and Inert; Limited Use in Vacuum or Reducing; Wide Temperature
Range; Most Popular Calibration
TEMPERATURE IN DEGREES °F
REFERENCE JUNCTION AT 32°F

Thermoelectric Voltage in Millivolts

°F	0	1	2	3	4	5	6	7	8	9	10	°F	°F	0	1	2	3	4	5	6	7	8	9	10	°F
700	15.179	15.203	15.226	15.250	15.273	15.296	15.320	15.343	15.366	15.390	15.413	700	1300	29.315	29.338	29.362	29.385	29.408	29.431	29.455	29.478	29.501	29.524	29.548	1300
710								15.577				710	1310				29.617								
720								15.811				720	1320				29.849								
730 740								16.045 16.280				730 740	1330				30.081								
740	10.110	10.139	10.103	10.100	10.209	10.233	10.230	10.200	10.303	10.327	16.330	740	1340	30.243	30.207	30.290	30.313	30.330	30.359	30.302	30.403	30.429	30.432	30.473	1340
750	16.350	16.374	16.397	16.421	16.444	16.468	16.491	16.514	16.538	16.561	16.585	750	1350	30.475	30.498	30.521	30.544	30.567	30.590	30.613	30.637	30.660	30.683	30.706	1350
760	16.585											760	1360				30.775								
770								16.984				770	1370				31.006								
780								17.220				780	1380				31.236								
790	17.290	17.314	17.337	17.361	17.384	17.408	17.431	17.455	17.478	17.502	17.526	790	1390	31.398	31.421	31.444	31.467	31.490	31.513	31.536	31.559	31.582	31.605	31.628	1390
800	17.526	17 549	17 573	17 596	17 620	17 643	17 667	17 690	17 714	17 738	17 761	800	1400	31.628	31.651	31 674	31.697	31 720	31 743	31 766	31 789	31.812	31.834	31.857	1400
	17.761											810	1410				31.926								
820	17.997											820	1420				32.156								
830	18.233											830	1430				32.385								
840	18.469	18.492	18.516	18.539	18.563	18.587	18.610	18.634	18.657	18.681	18.705	840	1440	32.545	32.568	32.591	32.614	32.636	32.659	32.682	32.705	32.728	32.751	32.774	1440
850	18.705	10 720	10 752	19 776	19 700	10 022	10 046	10 070	10 004	10 017	19 041	850	1450	32 774	32 706	32 810	32.842	32 865	32 888	32 011	33 033	32 056	32 070	33 003	1450
860	18.941											860	1460				33.070								
870	19.177											870	1470				33.298								
880	19.414											880	1480				33.526								
890	19.650	19.674	19.697	19.721	19.745	19.768	19.792	19.816	19.839	19.863	19.887	890	1490	33.685	33.708	33.730	33.753	33.776	33.798	33.821	33.844	33.867	33.889	33.912	1490
900	19.887	10.010	10.024	10.060	10 001	30 006	20.020	30.063	20.076	20 100	20 122	900	1500	33 012	22 025	22 057	33.980	34 003	34.025	34 049	34 071	34.003	24 116	24 120	1500
	20.123												1510	34.139											
	20.360											920	1520				34.433								
	20.597											930	1530				34.659								
940	20.834	20.857	20.881	20.905	20.929	20.952	20.976	21.000	21.023	21.047	21.071	940	1540	34.817	34.840	34.862	34.885	34.908	34.930	34.953	34.975	34.998	35.020	35.043	1540
0.00	21.071	24.004	21 110	21 142	21.100	21 100	24 242	24 220	24 200	24 204	24 200	050	1550	25 0 42	25.005	25 000	25 110	25 122	25.150	25 170	25 201	25 222	25.246	25 200	1550
	21.071 21.308											950 960	1550 1560	35.043 35.268											
	21.544											970	1570	35.493											
	21.781											980	1580												
990	22.018	22.042	22.066	22.089	22.113	22.137	22.160	22.184	22.208	22.232	22.255	990	1590	35.942	35.964	35.987	36.009	36.032	36.054	36.076	36.099	36.121	36.144	36.166	1590
1000	22.255	22.270	22 202	22.224	22.250	22.274	22.207	22.424	22.445	20.400	22.402	1000	1000	00.100	20 100	20.244	20 222	20.200	20.070	20.200	20.222	20.245	20.007	20.200	1000
	22.255 22.492												1600 1610	36.166			36.233								
	22.729												1620	36.613											
	22.966												1630	36.836											
1040	23.203	23.226	23.250	23.274	23.297	23.321	23.345	23.368	23.392	23.416	23.439	1040	1640	37.059	37.081	37.104	37.126	37.148	37.170	37.193	37.215	37.237	37.259	37.281	1640
	23.439 23.676												1650 1660				37.348 37.570								
	23.913												1670				37.792								
	24.149												1680				38.013								
1090	24.386	24.409	24.433	24.457	24.480	24.504	24.527	24.551	24.575	24.598	24.622	1090	1690	38.168	38.190	38.212	38.235	38.257	38.279	38.301	38.323	38.345	38.367	38.389	1690
	24.622 24.858												1700				38.455 38.676								
	25.094												1770				38.896								
	25.330												1730				39.116								
1140	25.566	25.590	25.613	25.637	25.660	25.684	25.708	25.731	25.755	25.778	25.802	1140	1740	39.270	39.292	39.314	39.335	39.357	39.379	39.401	39.423	39.445	39.467	39.489	1740
	25.802												1750	39.489											
	26.037 26.273												1760	39.708			39.774								
	26.508													40.145											
	26.743													40.363											
													2003000												
	26.978													40.581											
	27.213 27.447													40.798 41.015											
	27.681													41.232											
	27.915												1840	41.449	41.470	41.492	41.514	41.535	41.557	41.578	41.600	41.622	41.643	41.665	1840
													200000												
	28.149													41.665											
	28.383												1860				41.945								
	28.616 28.849												1870	42.096			42.161								
	29.082													42.526											
													9730000												
°F	0	1	2	3	4	5	6	7	8	9	10	°F	°F	0	1	2	3	4	5	6	7	8	9	10	°F

MAXIMUM TEMPERATURE RANGE

MAXIMUM TEMPERATURE RANGE
Thermocouple Grade

- 328 to 2282°F
- 200 to 1250°C

Extension Grade
32 to 392°F
0 to 200°C

LIMITS OF ERROR
(whichever is greater)
Standard: 2.2°C or 0.75% Above 0°C
2.2°C or 2.0% Below 0°C
Special: 1.1°C or 0.4%
COMMENTS, BARE WIRE ENVIRONMENT:
Clean Oxidizing and Inert; Limited Use in
Vacuum or Reducing; Wide Temperature
Range; Most Popular Calibration
TEMPERATURE IN DEGREES °F
REFERENCE JUNCTION AT 32°F



Extension Grade

Thermocouple Grade

Nickel-Chromium

Nickel-Aluminum



Revised Thermocouple Reference Tables

Reference **Tables** N.I.S.T. Monograph 175 Revised to ITS-90



Z

Thermoelectric Voltage in Millivolts

°F	0	1	2	3	4	5	6	7	8	9	10	°F		°F	0	1	2	3	4	5	6	7	8	9	10	°F
1900	42.741	42.762	42.783	42.805	42.826	42.848	42.869	42.891	42.912	42.933	42.955	1900	2	250	50.006	50.026	50.046	50.066	50.086	50.106	50.126	50.146	50.166	50.186	50.206	2250
1910	42.955	42.976	42.998	43.019	43.040	43.062	43.083	43.104	43.126	43.147	43.169	1910	2	260	50.206	50.226	50.246	50.266	50.286	50.306	50.326	50.346	50.366	50.385	50.405	2260
1920	43.169	43.190	43.211	43.233	43.254	43.275	43.297	43.318	43.339	43.361	43.382	1920	2	270	50.405	50.425	50.445	50.465	50.485	50.505	50.525	50.545	50.564	50.584	50.604	2270
1930	43.382	43.403	43.425	43.446	43.467	43.489	43.510	43.531	43.552	43.574	43.595	1930	2	280	50.604	50.624	50.644	50.664	50.684	50.703	50.723	50.743	50.763	50.783	50.802	2280
1940	43.595	43.616	43.638	43.659	43.680	43.701	43.723	43.744	43.765	43.787	43.808	1940	2	290	50.802	50.822	50.842	50.862	50.882	50.901	50.921	50.941	50.961	50.981	51.000	2290
1950	43.808	43.829	43.850	43.872	43.893	43.914	43.935	43.957	43.978	43.999	44.020	1950	2	300	51.000	51.020	51.040	51.060	51.079	51.099	51.119	51.139	51.158	51.178	51.198	2300
1960	44.020	44.041	44.063	44.084	44.105	44.126	44.147	44.169	44.190	44.211	44.232	1960	2	310	51.198	51.217	51.237	51.257	51.276	51.296	51.316	51.336	51.355	51.375	51.395	2310
1970	44.232	44.253	44.275	44.296	44.317	44.338	44.359	44.380	44.402	44.423	44.444	1970	2	320	51.395	51.414	51.434	51.453	51.473	51.493	51.512	51.532	51.552	51.571	51.591	2320
	44.444																	51.650								
1990	44.655	44.676	44.697	44.719	44.740	44.761	44.782	44.803	44.824	44.845	44.866	1990	2	340	51.787	51.806	51.826	51.845	51.865	51.885	51.904	51.924	51.943	51.963	51.982	2340
2000	44.866	44.887	44.908	44.929	44.950	44.971	44.992	45.014	45.035	45.056	45.077	2000						52.041								
	45.077																	52.235								
2020	45.287	45.308	45.329	45.350	45.371	45.392	45.413	45.434	45.455	45.476	45.497	2020	2	370	52.371	52.391	52.410	52.430	52.449	52.468	52.488	52.507	52.527	52.546	52.565	2370
	45.497												2	380				52.623								
2040	45.706	45.727	45.748	45.769	45.790	45.811	45.832	45.852	45.873	45.894	45.915	2040	23	39052	.759	52.778	52.797	52.817	52.836	52.855	52.875	52.894	52.913	52.932	52.952	2390
	45.915																	53.010								
	46.124																	53.202								
	46.332																	53.394								
	46.540																	53.585								
2090	46.747	46.768	46.789	46.809	46.830	46.851	46.871	46.892	46.913	46.933	46.954	2090	2	440	53.719	53.738	53.757	53.776	53.795	53.814	53.833	53.852	53.871	53.890	53.910	2440
													١.,													
	46.954																	53.967								
	47.161																	54.157								
	47.367																	54.346								
	47.573																	54.536								
2140	47.778	47.798	47.819	47.839	47.860	47.880	47.901	47.921	47.942	47.962	47.983	2140	2	490	54.668	54.687	54.705	54.724	54.743	54.762	54./81	54.800	54.819	54.837	54.856	2490
2160	47.983	40.002	40.004	40.044	40.006	40.00€	40 106	40 126	40 146	40 167	40 107	2160	١,	E00	54.856	E 4 07 E	£4.00.4									2500
	48.187												4	300	34.030	34.073	34.034									2300
	48.391																									
	48.595																									
	48.798																									
2190	40.790	40.010	40.030	40.039	40.079	40.099	40.919	40.340	40.900	40.300	45.000	2 190														
2200	49.000	40.021	40.041	40.061	40.001	40 101	40 122	40 142	40 162	40 102	40.202	2200														
	49.202																									
	49.404																									
	49.605																									
	49.806																									
°F	0	1	2	3	4	5	6	7	8	9	10	°F		۰E	0	1	2	3	4	5	6	7	8	0	10	°F
г	J		2	3	4	3	0	,	0	3	10	г	1		J	•	2	3	4	3	0	,	6	3	10	1'